

Dr.-Ing. Marcus Bär

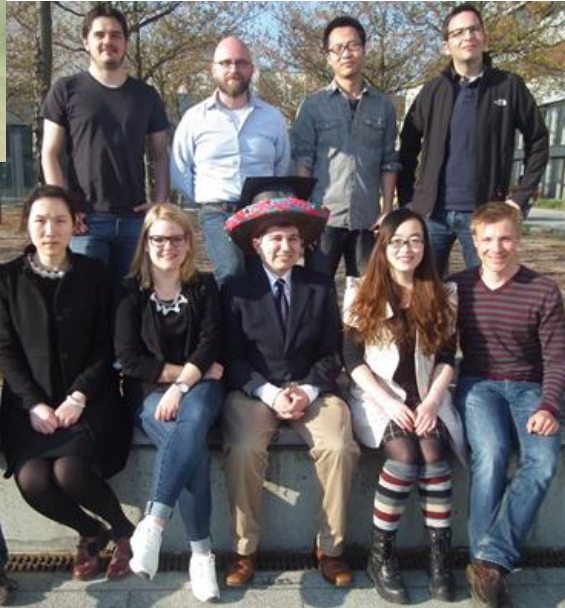
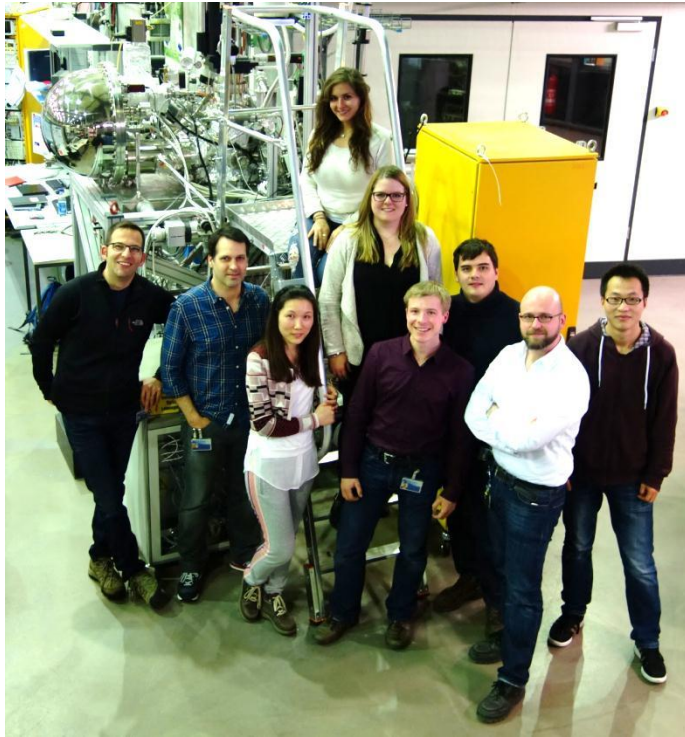
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**EMIL - Experimental Capabilities of the Energy
Materials In-Situ Laboratory**

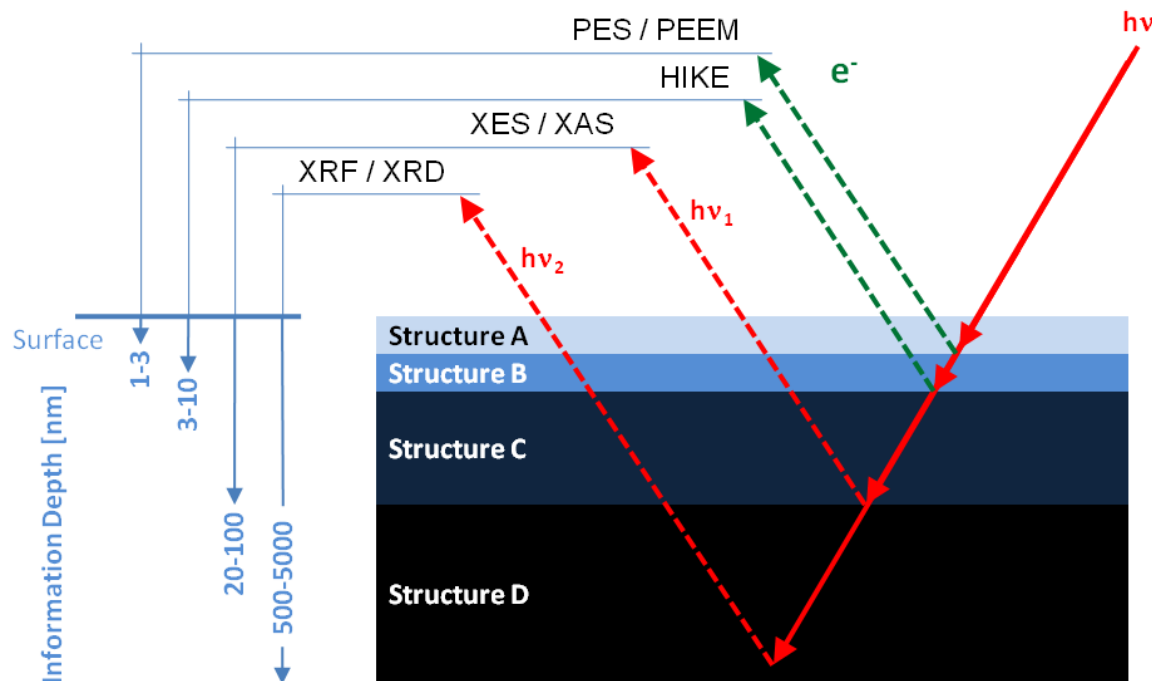
Acknowledgements



- Dr. Regan G. Wilks
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- Dr. Raul Garcia Diez
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- Dr. Xeniya Kozina
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- **(Dr. David Starr)**
- Ting Xiao
- Penghui Yang
- **Claudia Hartmann**
- Jakob Bombsch
- Andreas Siebert
- Dongyang Liu

Open questions in energy materials research

- Chemical/electronic structure?
- Band alignment?
- Compound formation?
- Stability?
- Charge carrier separation/transport?
- Secondary phases?

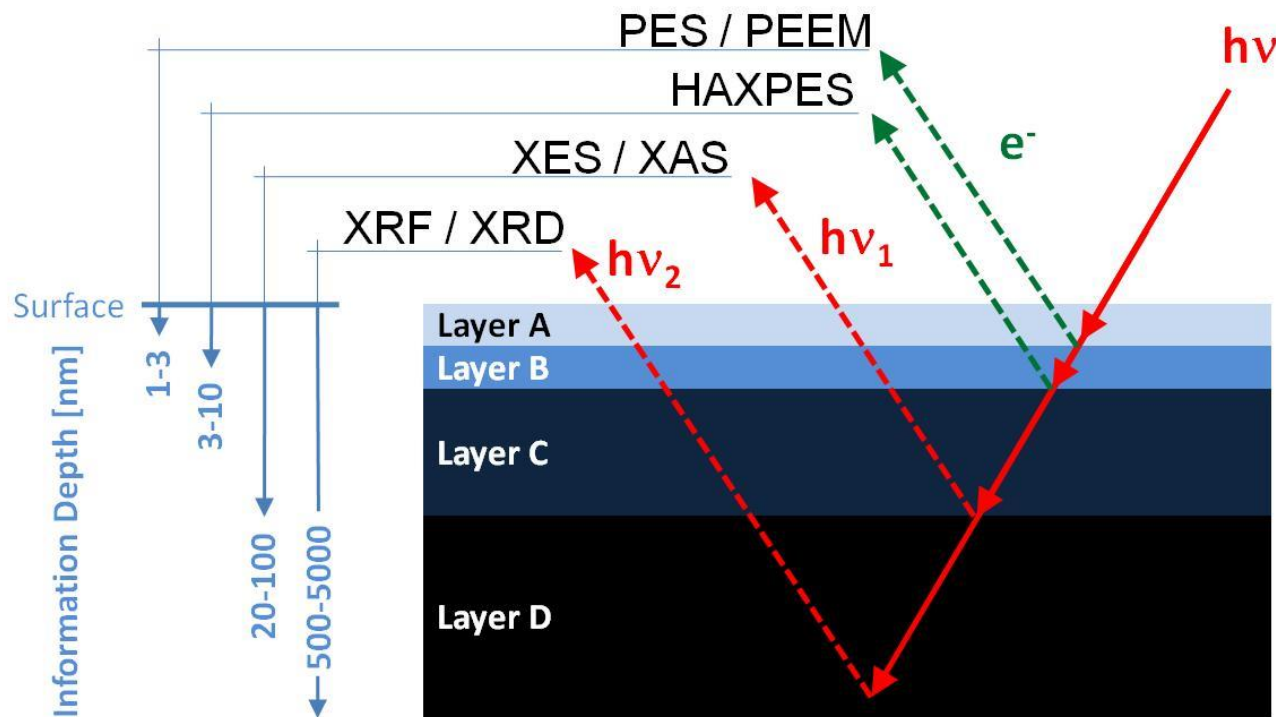


advanced analytics (permanent access & “two color” beamline)
& deposition tools (industry-scale & connected via UHV transfer)



EMIL

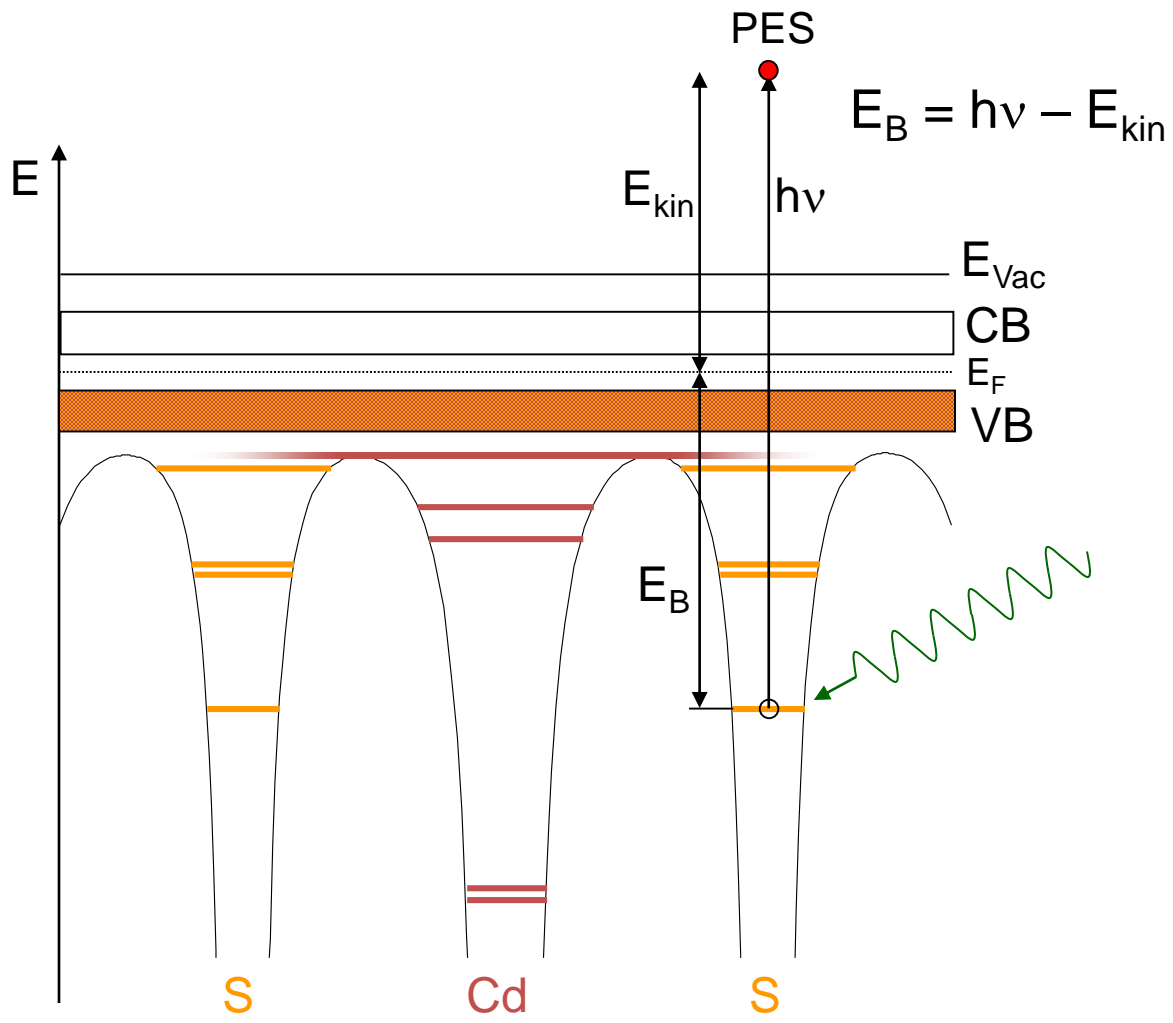
Uniquely suited for tomorrow's energy materials research!



PES – Photoelectron spectroscopy
PEEM – Photoemission electron microscopy
HAXPES – Hard X-ray PES

XES – X-ray emission spectroscopy
XAS – X-ray absorption spec.
XRF – X-ray fluorescence spec.
XRD – X-ray diffraction spec.

Photoelectron Spectroscopy (PES): Principle



X-ray PES (XPS, ESCA)

+ AES:

$h\nu \sim 100 - 1500 \text{ eV}$

- Core levels
- Composition of surface
- Chemical species

Experimental Setup

Excitation source:

X-ray tube:

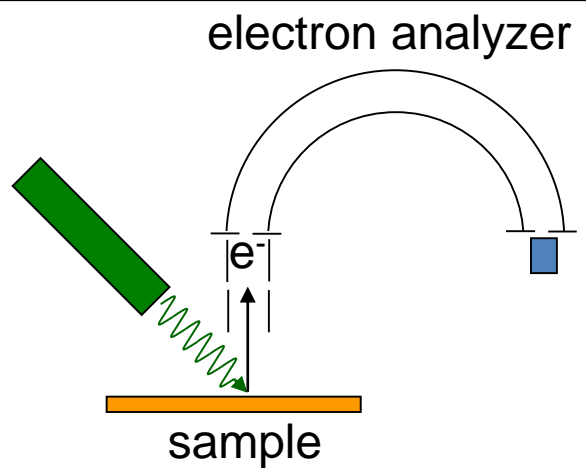
- Mg K_{α} (~1254 eV)
- Al K_{α} (~1486 eV)

UV-lamp:

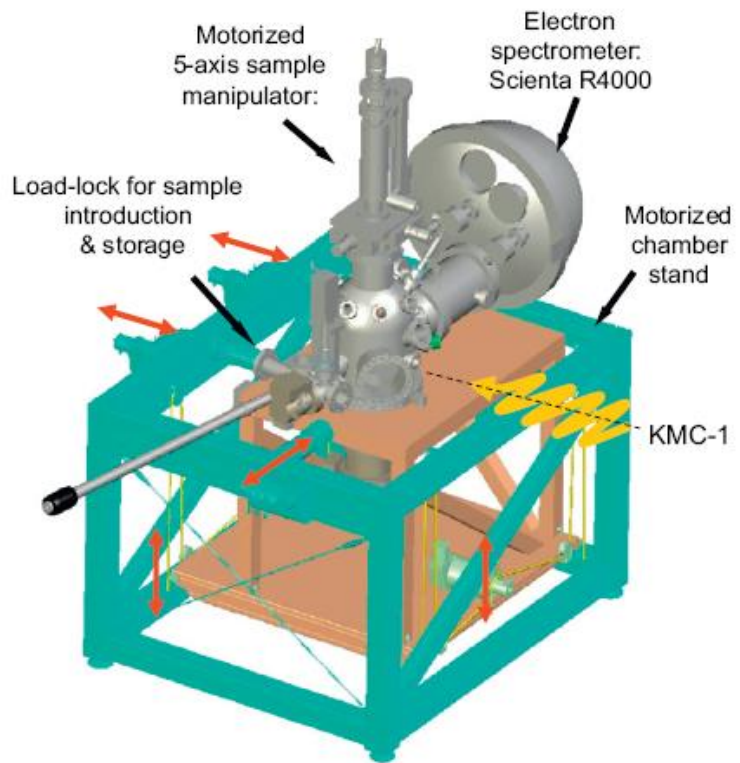
- He I (21.2 eV)
- He II (40.8 eV)
- Ne I (16.7 eV)
- Ar I (11.7 eV)

Synchrotron:

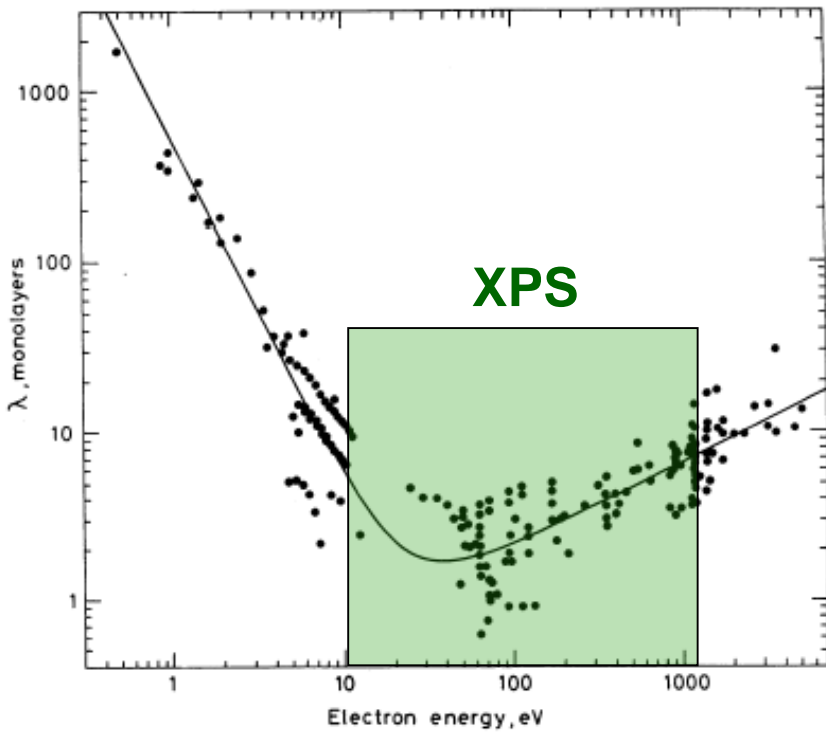
10 - 15.000 eV



electron analyzer



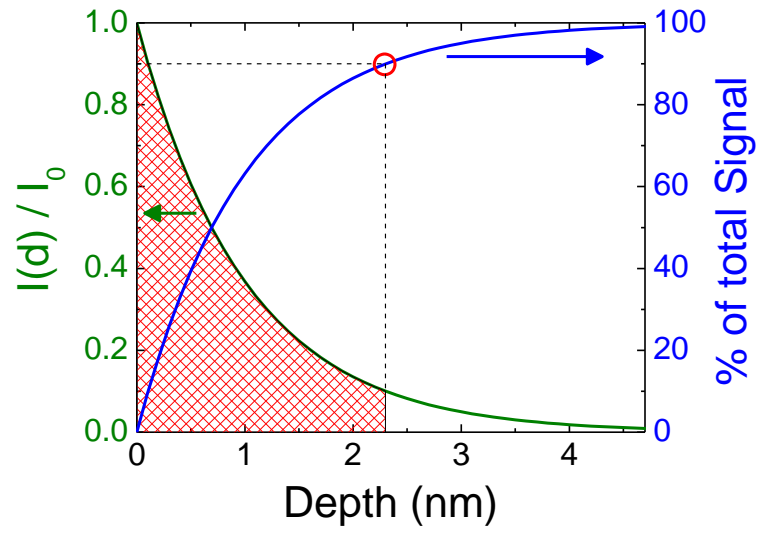
PES: Surface Sensitivity



D. Briggs, M.P. Seah, "Practical Surface Analysis" (1990)

$$I(d) = I_0 \cdot e^{-d/\lambda}$$

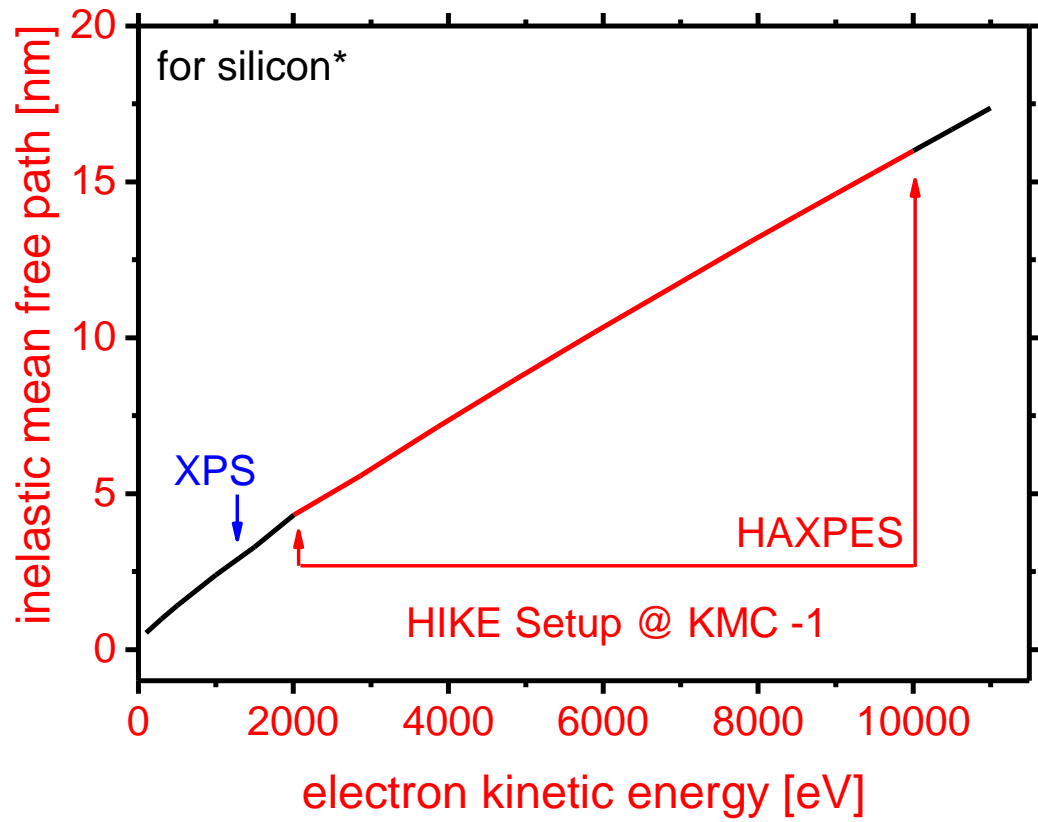
λ : inelastic mean free path



Values can be obtained from:

S. Tanuma et al., Surf. Interf. Anal., Vol. 21, 165 (1993)
http://www.quases.com/frames/samples_and_downloads.htm

XPS vs. HAXPES: PROBING DEPTH



Probing depth is governed by:

XPS: Inelastic mean free path (a few Å)

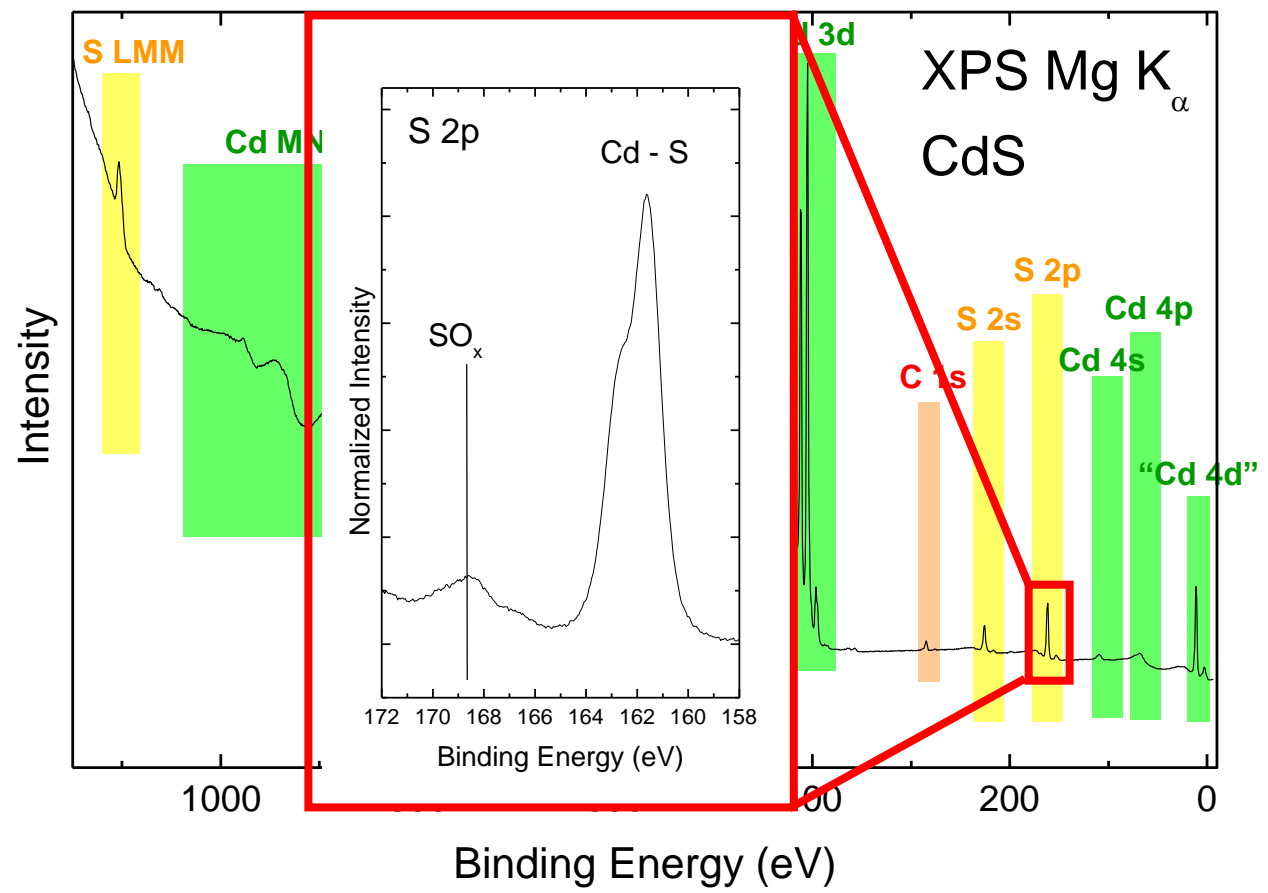
HAXPES: Inelastic mean free path (several nm to a few 10 nm)

according to:

$$I = I_0 \exp(-x/\lambda)$$

*based on S. Tanuma, C. J. Powell, D. R. Penn, Surf. Interf. Anal. 21, 165 (1993).

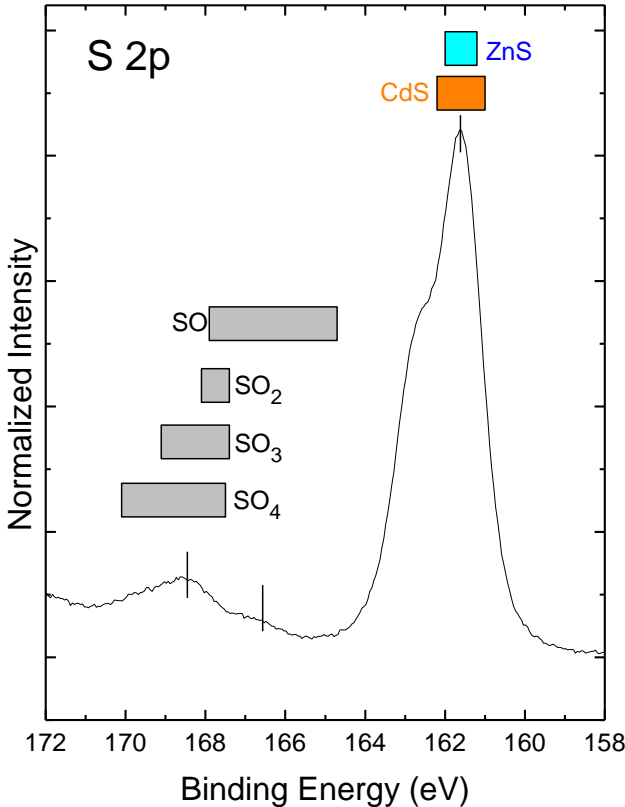
(HA)XP(E)S: Qualitative Information



XPS gives information about elements at surface and chemical compounds (chemical shift)

(HA)XP(E)S (+AES): Chemical shifts

- Energy positions of core levels and Auger lines shift for different chemical compounds
- But: determination of chemical compound typically needs more than just one line position!
- To eliminate effects of band bending and charging the use of the Modified Auger Parameter can be used:



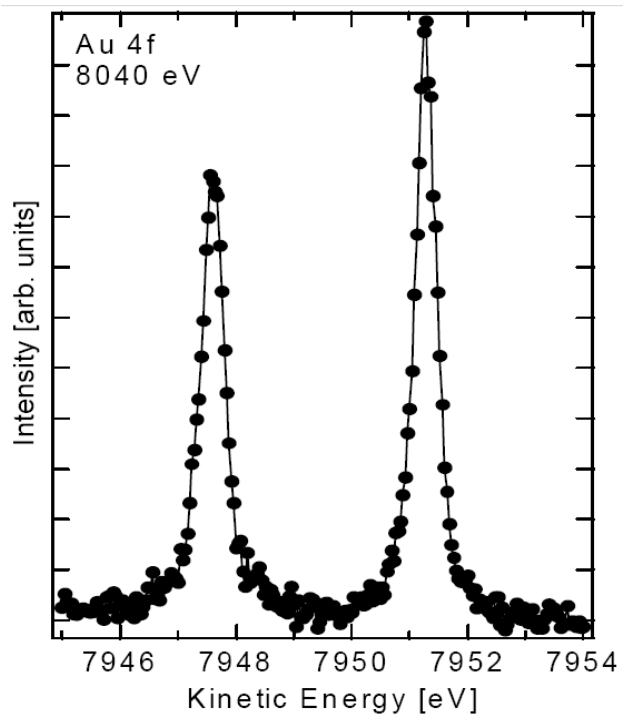
$$\alpha^* = \alpha + h\nu = E_{kin}^{Auger} + E_B^{PES}$$

Cd	3d5/2	CdO	404	Click
Cd	3d5/2	CdO	404.2	Click
Cd	3d5/2	CdCr0.3In1.7S4	405.4	Click
Cd	3d5/2	CdCr0.3In1.7S4	405.4	Click
Cd	3d5/2	CdS	405.4	Click
Cd	3d5/2	CdS	405.2	Click
Cd	3d5/2	CdS	405.3	Click
Cd	3d5/2	CdS	405.5	Click
Cd	3d5/2	CdS	405.1	Click
Cd	3d5/2	CdS	405.3	Click
Cd	3d5/2	CdS	405.4	Click
Cd	3d5/2	CdSe	405.3	Click
Cd	3d5/2	CdSe	405	Click
Cd	3d5/2	Ba/Ca/Cd/Sr/in_montmorillonite	406.4	Click

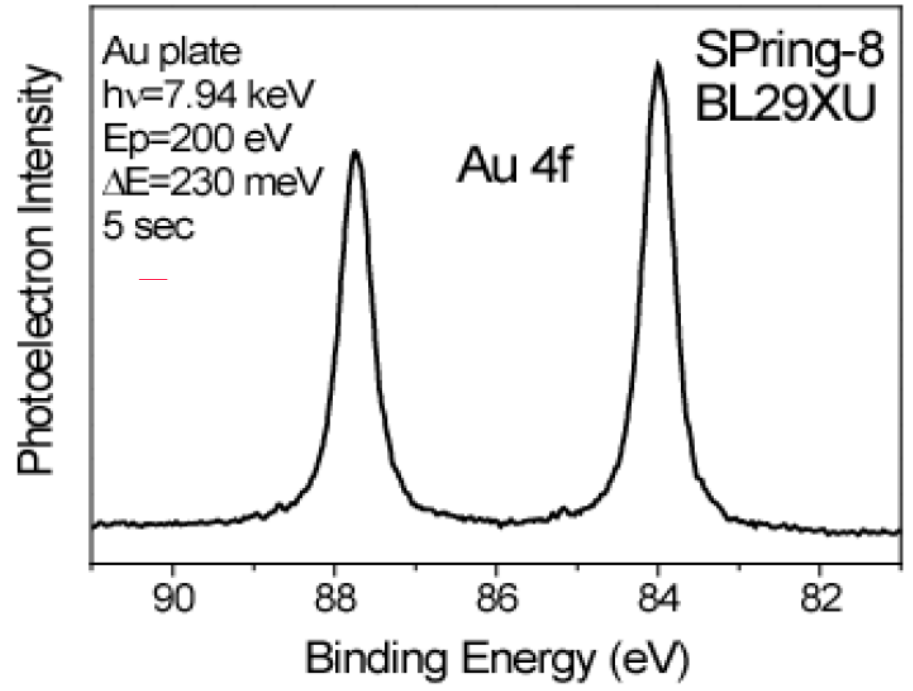
<http://srdata.nist.gov/xps/>

HAXPES: Current state-of-the-art

M. Gorgoi et al, The European Physical Journal **169**, 227 (2009).



Courtesy of Y. Takata



HIKE: 7200s

SPring-8: 5s

- Hard x-ray EMIL beamline (w/ cryogenic undulator) is expected to provide higher flux than current HIKE beamline

XPS: Quantification

Element
 ↓
 Line (e.g. 2p)
 ↓

$$I \propto \sigma(Z, N, h\nu) \cdot T(E_{kin}) \cdot L(\gamma, N) \cdot \int_0^d c(Z, x) \cdot e^{-x \cos \theta / \lambda(E_{kin})} dx$$

Layer thickness
 ↙

$\sigma(Z, N, h\nu)$: Photoionization cross section
 e.g. from **Yeh and Lindau, Atomic Data and Nuclear Data Tables 32 (1985)**

$T(E_{kin})$: Electron Analyzer Transmission

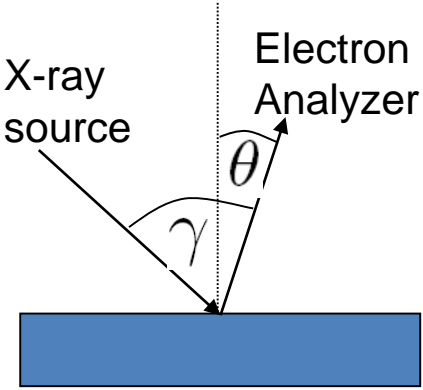
$L(\gamma, N) = 1 + \frac{1}{2}\beta(N) \left(\frac{3}{2} \sin^2 \gamma - 1 \right)$: angular asymmetry factor (=1 for "Magic Angle" of 54.7°)

$\lambda(E_{kin})$: inelastic mean free path (of the electrons)

$c(Z, x)$: concentration of element Z

Homogeneous layer, $d \rightarrow \infty, \theta = 0$:

$$\frac{c(A)}{c(B)} = \frac{I(A)}{I(B)} \cdot \frac{\sigma_B \cdot T_B \cdot \lambda_B}{\sigma_A \cdot T_A \cdot \lambda_A}$$



XPS: Quantification

Element
 ↓
 Line (e.g. 2p)
 ↓

$$I \propto \sigma(Z, N, h\nu) \cdot T(E_{kin}) \cdot L(\gamma, N) \cdot \int_0^d c(Z, x) \cdot e^{-x \cos \theta / \lambda(E_{kin})} dx$$

Layer thickness
 ↓

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 e.g. from Yeh and Lindau, Atomic Data and Nuclear Data Tables **32** (1985)
 J. H. Scofield, J. Electron Spectrosc. Relat. Phenom. **8**, 129 (1976).

$T(E_{kin})$: Electron Analyzer Transmission
 -> similar for similar kinetic energies

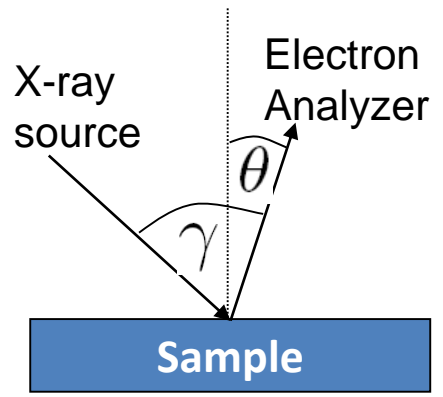
$L(\gamma, N) = 1 + \frac{1}{2}\beta(N) \left(\frac{3}{2} \sin^2 \gamma - 1 \right)$: angular asymmetry factor (=1 for "Magic Angle" of 54.7°)

$\lambda(E_{kin})$: inelastic mean free path „IMFP“ (of the electrons)
 -> similar for similar kinetic energies

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Homogeneous layer, $d \rightarrow \infty, \theta = 0$:

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XPS: Quantification

Element
 ↓
 Line (e.g. 2p)
 ↓

$$I \propto \sigma(Z, N, h\nu) \cdot T(E_{kin}) \cdot L(\gamma, N) \cdot \int_0^d c(Z, x) \cdot e^{-x \cos \theta / \lambda(E_{kin})} dx$$

Layer thickness
 ↙

$\sigma(Z, N, h\nu)$: Photoionization cross section
 -> same for one photoemission line.

$T(E_{kin})$: Electron Analyzer Transmission
 -> same for one photoemission line

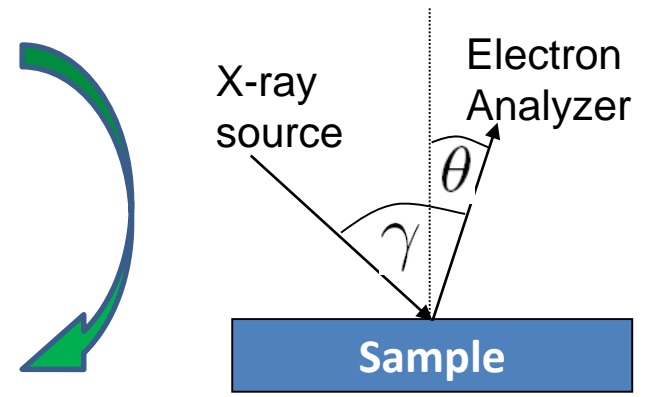
$L(\gamma, N) = 1 + \frac{1}{2}\beta(N) \left(\frac{3}{2} \sin^2 \gamma - 1 \right)$: angular asymmetry factor -> same for one photoemission line

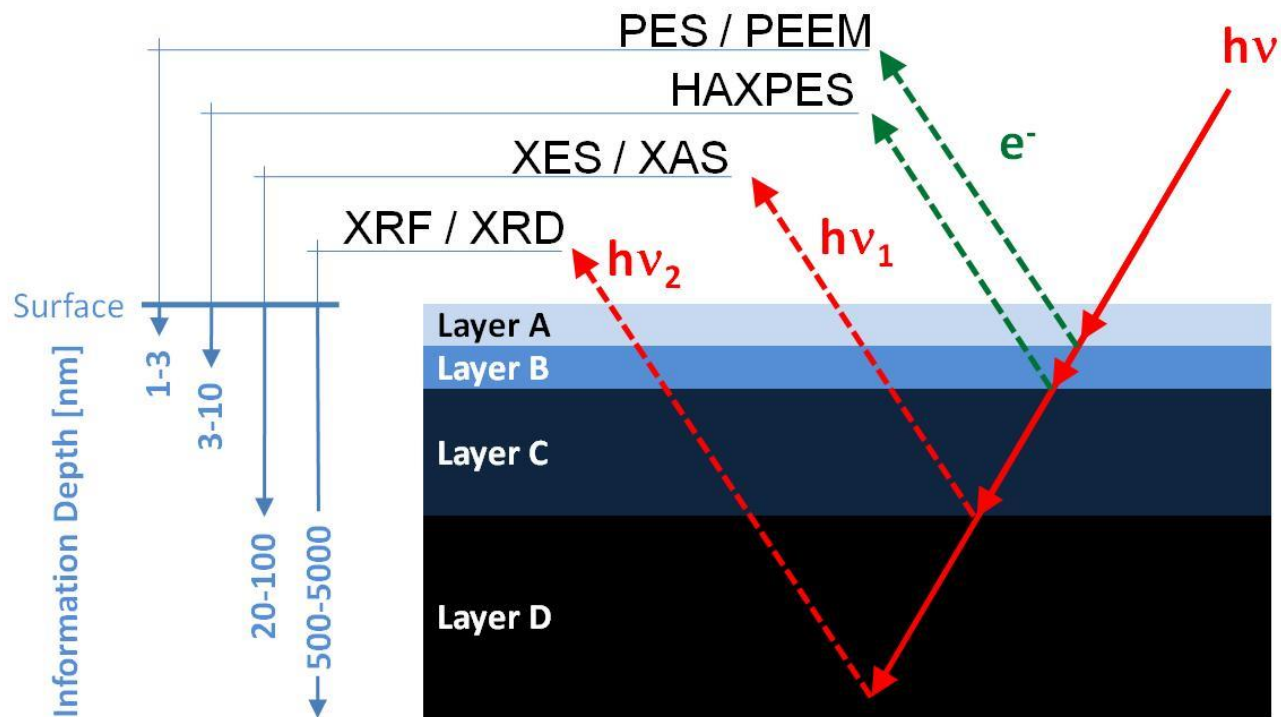
$\lambda(E_{kin})$: inelastic mean free path „IMFP“ (of the electrons)
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Homogeneous layer, $d \rightarrow \infty, \theta = 0$:

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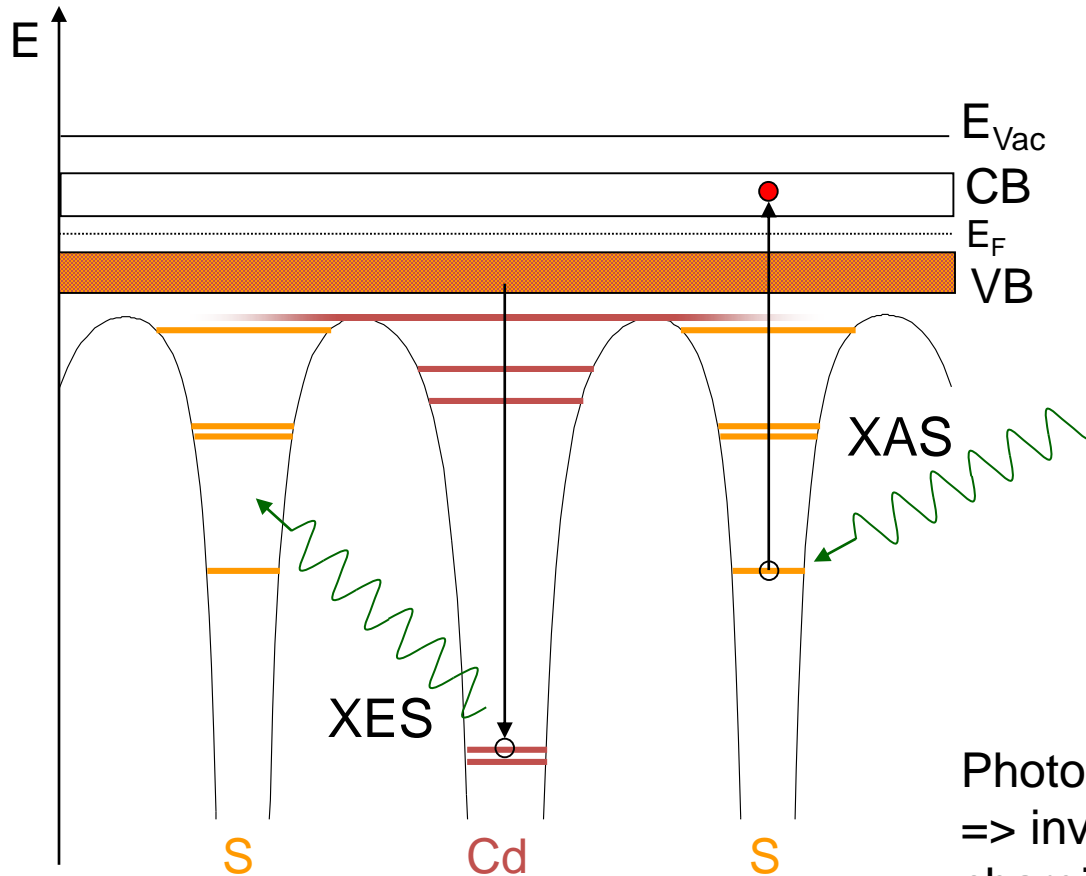




PES – Photoelectron spectroscopy
PEEM – Photoemission electron microscopy
HAXPES – Hard X-ray PES

XES – X-ray emission spectroscopy
XAS – X-ray absorption spec.
XRF – X-ray fluorescence spec.
XRD – X-ray diffraction spec.

X-ray absorption spectroscopy (XAS) and x-ray emission spectroscopy (XES): Principle



XAS:

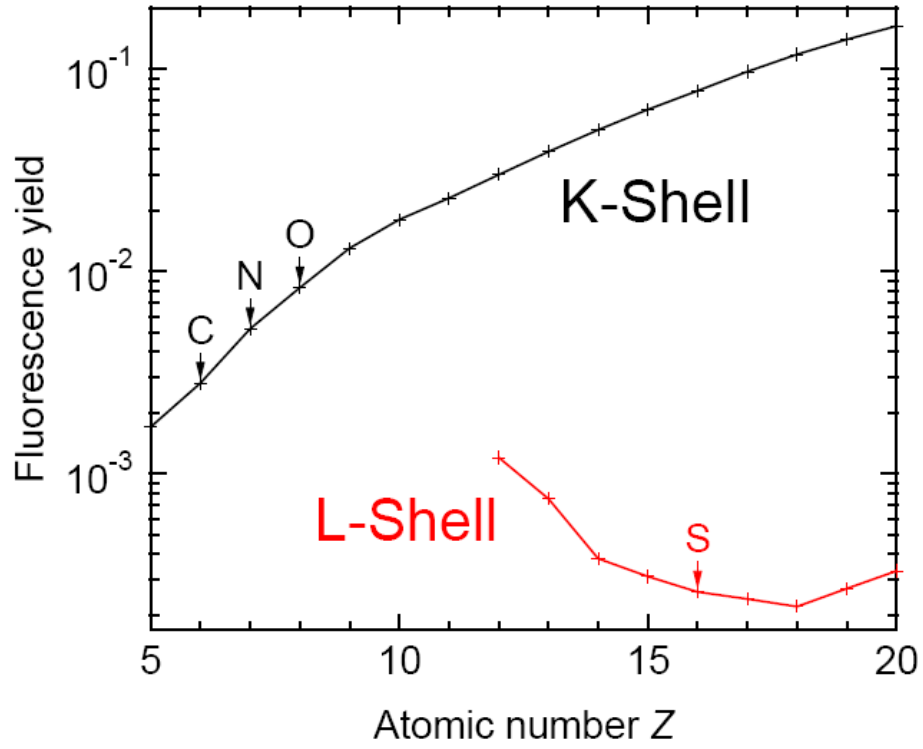
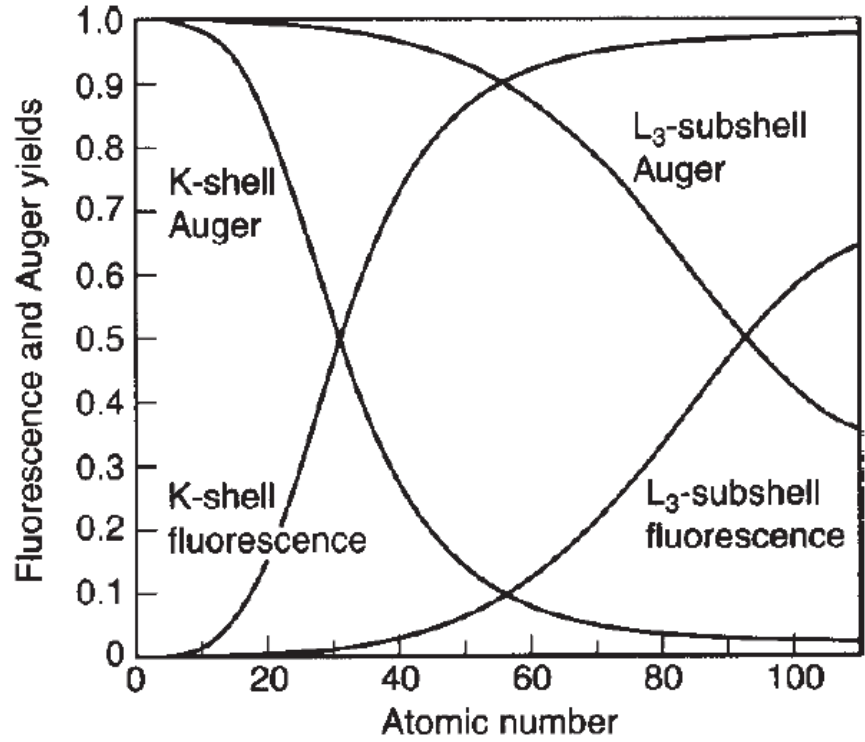
- Conduction band from the "perspective of a chosen core hole" (wave function overlap is needed)

XES:

- Valence band and weakly bound core levels from the "perspective of a chosen core hole"

Photon in - photon out techniques
=> investigation of buried interface,
charging samples, liquids,...

Fluorescence vs. Auger process

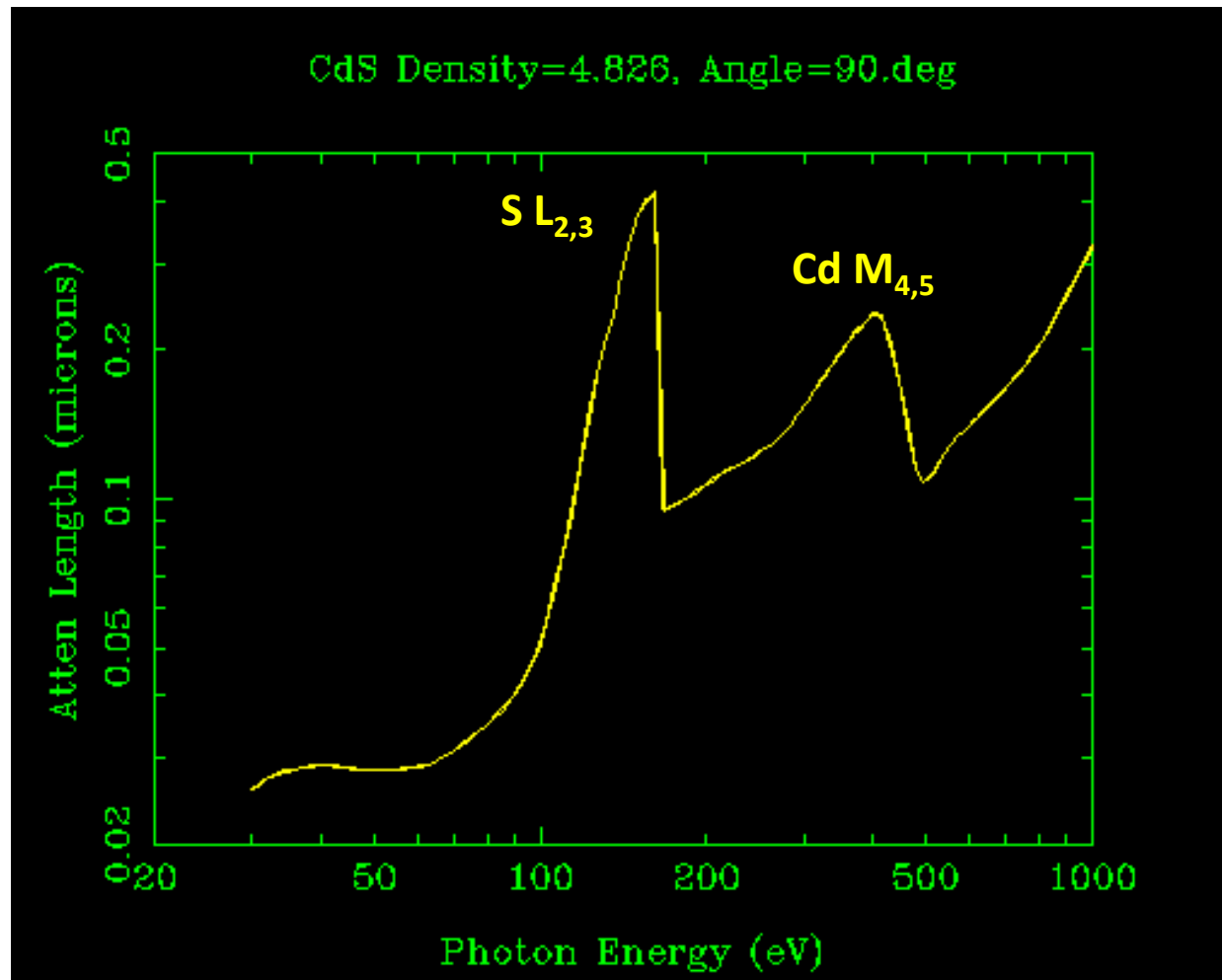


T. Attwood, *Soft X-rays and extreme ultraviolet radiation: principles*, Cambridge University Press (1999).
 M. O. Krause, *Atomic radiative and radiationless yields for K-shells and L-shells*, *J. Phys. Chem. Ref. Data* 8, 307 (1979).

Need for high-flux beamline at a 3rd generation synchrotron light source!

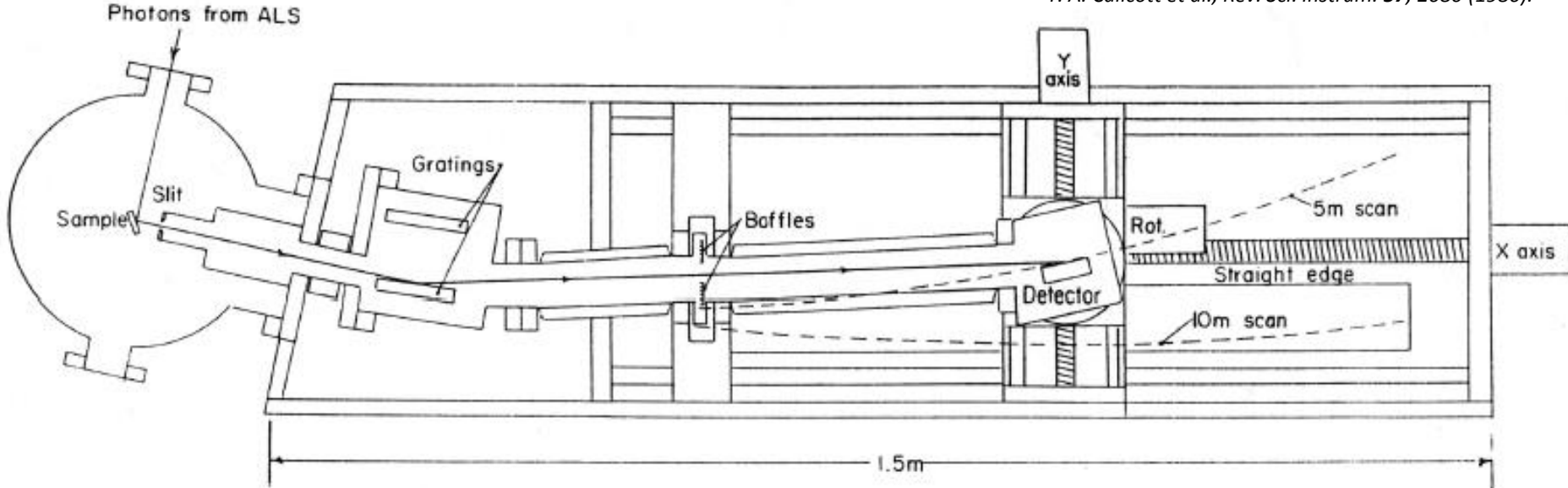
XES: Probing depth

- "photon in - photon out" technique
- More bulk sensitive than photoemission
- Attenuation lengths: some 10 ... few 100 nm

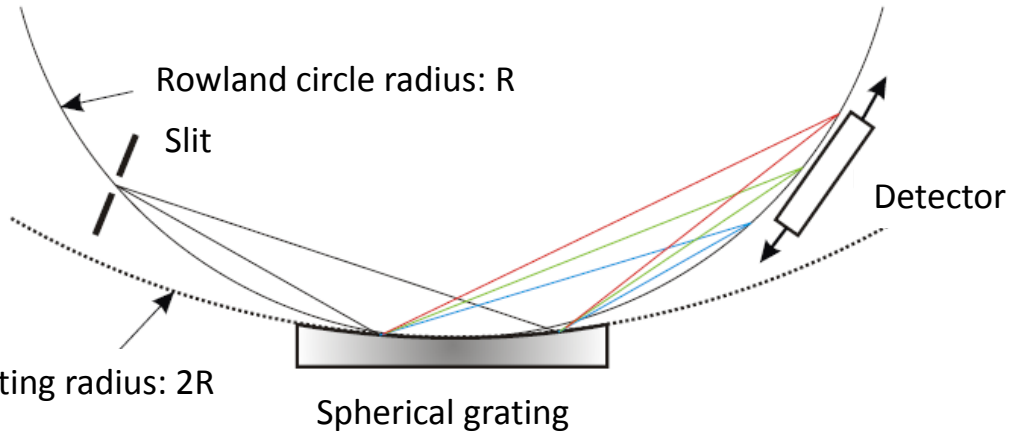


XES & XAS: Experimental setup

T. A. Callcott et al., Rev. Sci. Instrum. 57, 2680 (1986).

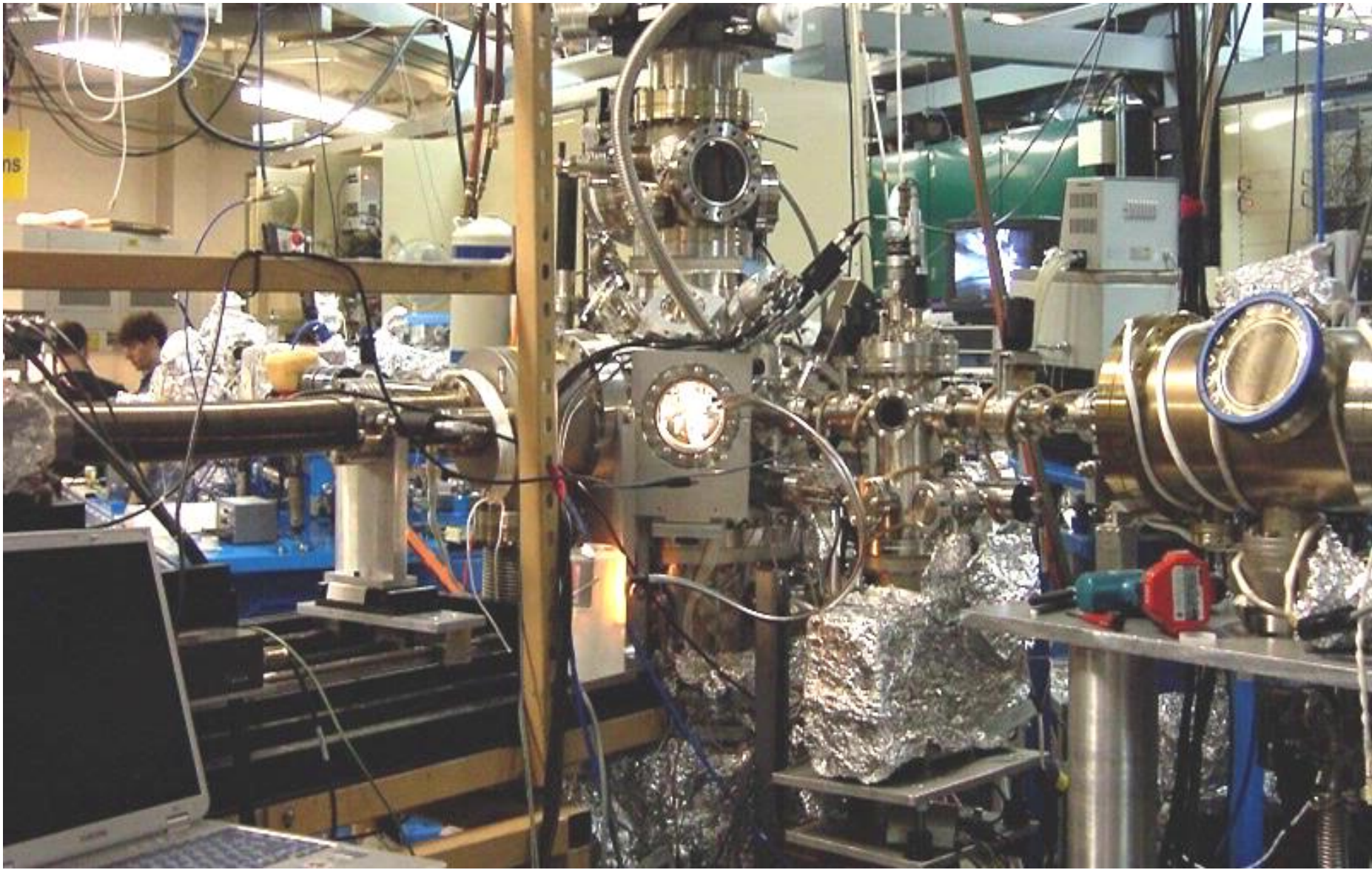


- XES: Grating spectrometer (Rowland geometry) for energy dispersive photon detection
- XAS: Photon/Electron detection
- High-flux beamline at a 3rd generation synchrotron is needed



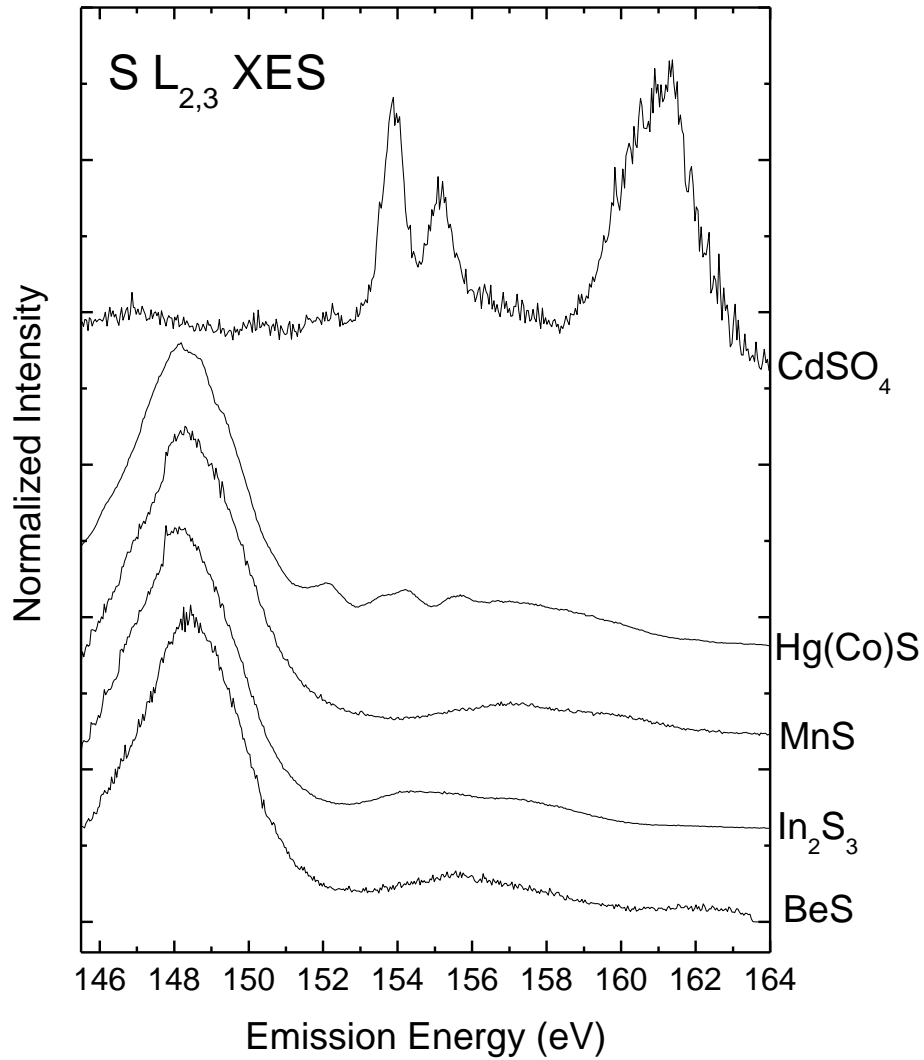
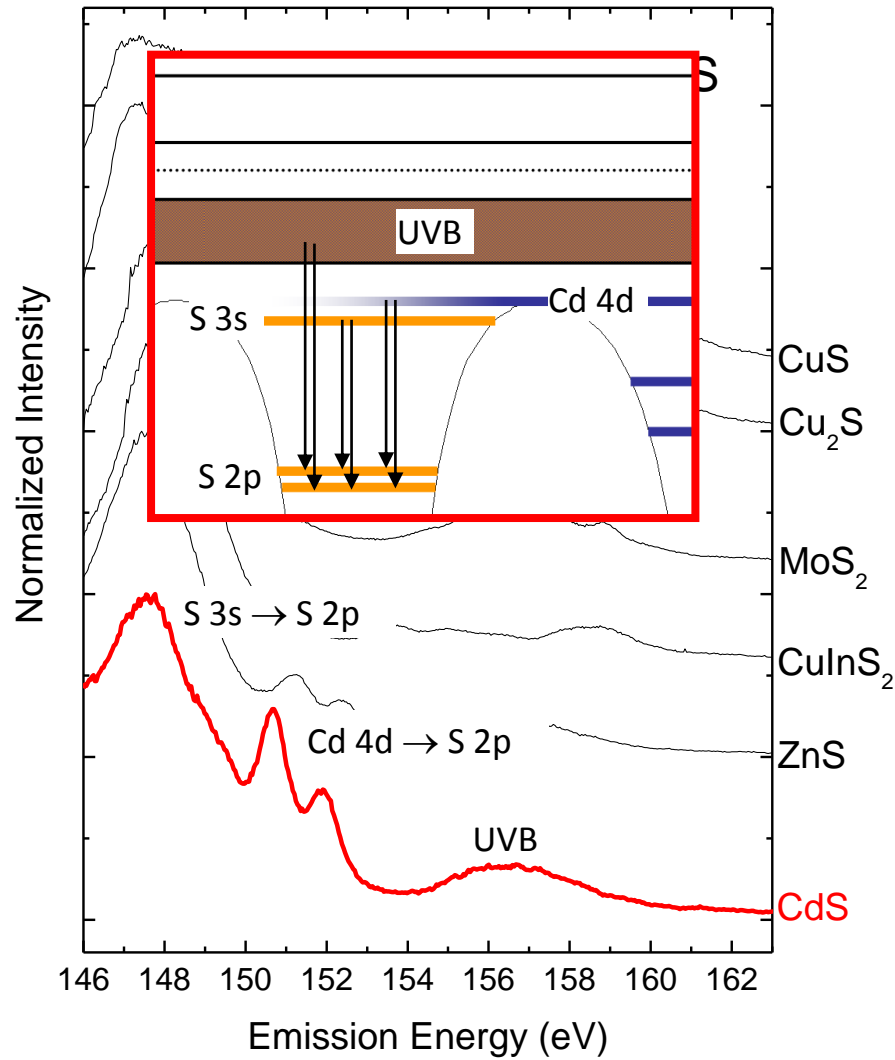
H. A. Rowland, Philos. Mag. 13, 469 (1882).

Experimental setup in real life



XES example: S $L_{2,3}$ emission spectrum

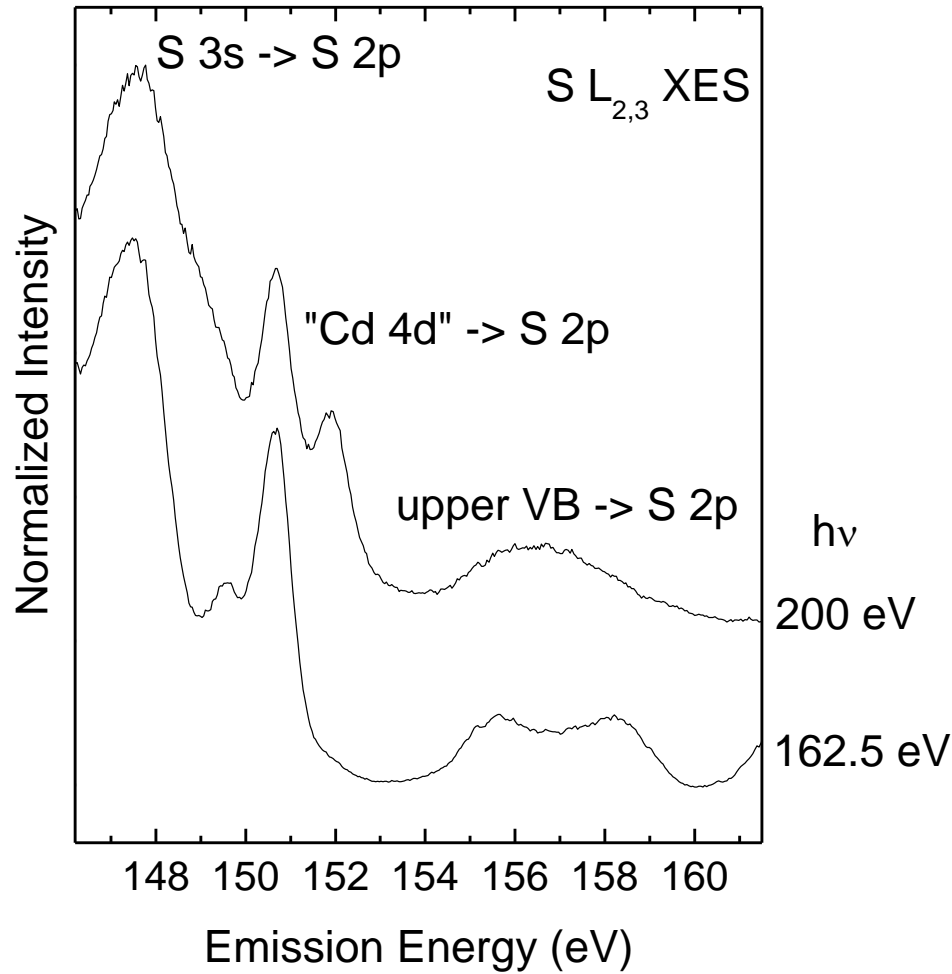
„Fingerprint“ approach => identification of different species



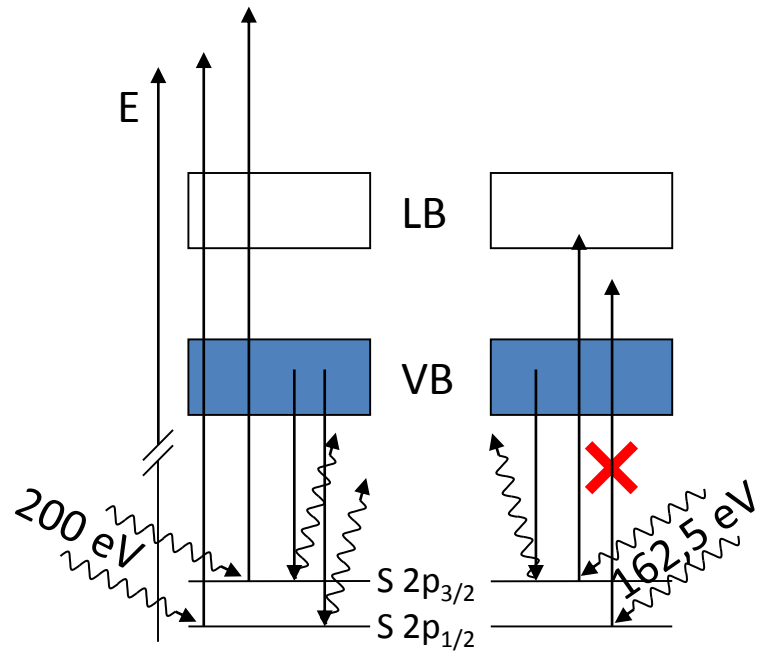
Courtesy of L. Weinhardt

„Resonant“ excitation

Weinhardt et al., PRB 75, 165207 (2007).

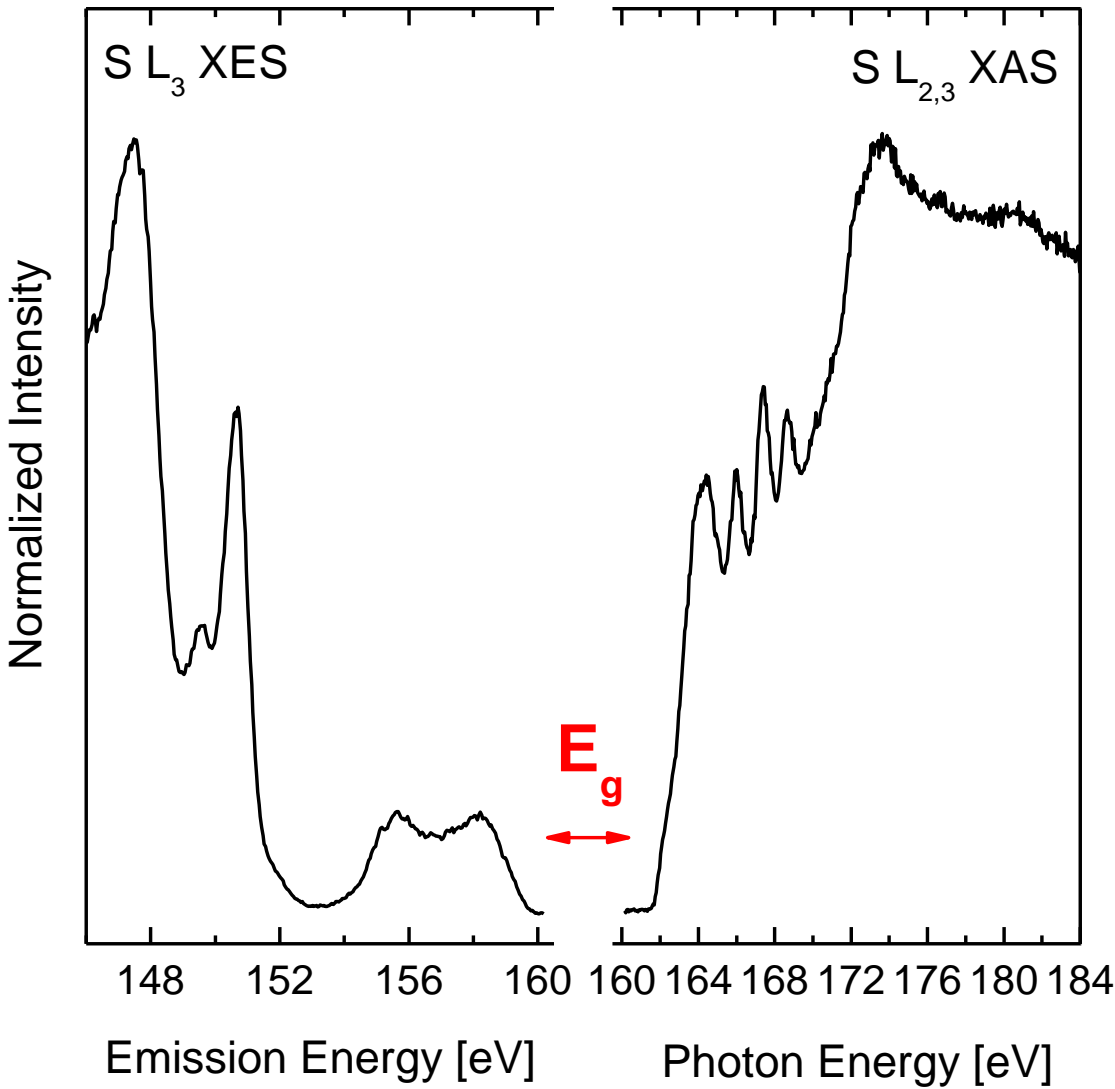


- Wave function overlap between Cd 4d-derived states and S 2p
- L₂ and L₃ contribution to the spectrum can be separated



Combination of XES & XAS spectra

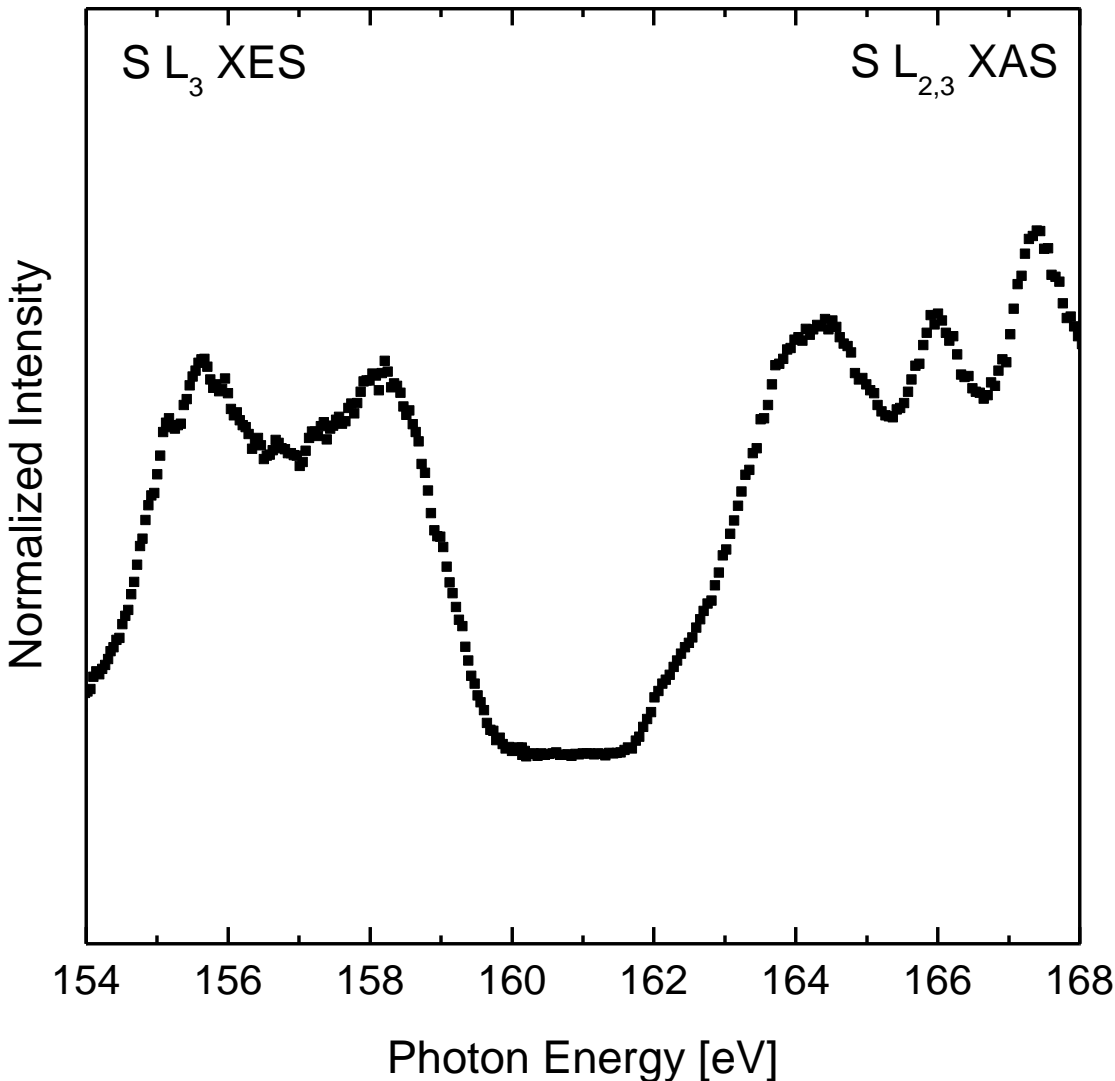
Weinhardt et al., PRB 75, 165207 (2007).



- XES probes occupied states
=> Onset indicative for VBM
- XAS probes unoccupied states
=> Onset indicative for CBM

Combination of XES & XAS spectra

Weinhardt et al., PRB 75, 165207 (2007).



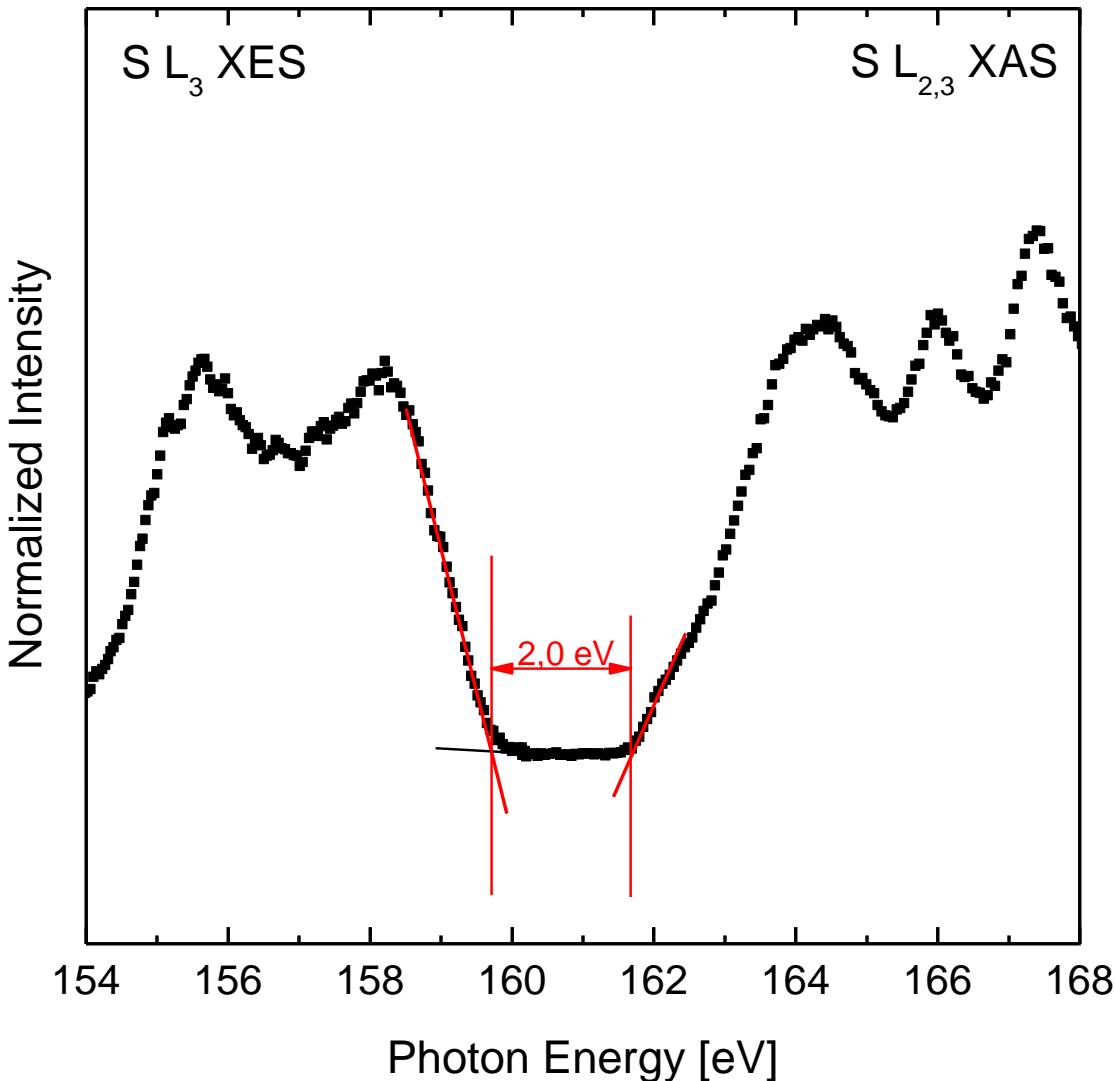
- XES probes occupied states
=> Onset indicative for VBM
- XAS probes unoccupied states
=> Onset indicative for CBM
- XES & XAS probe “E_g”
(experimental uncertainty: ± 0.2 eV)
- Potential existence of core excitonic features in the XAS spectra



“E_g” is lower-bound approximation for the ground state band gap

Combination of XES & XAS spectra

Weinhardt et al., PRB 75, 165207 (2007).



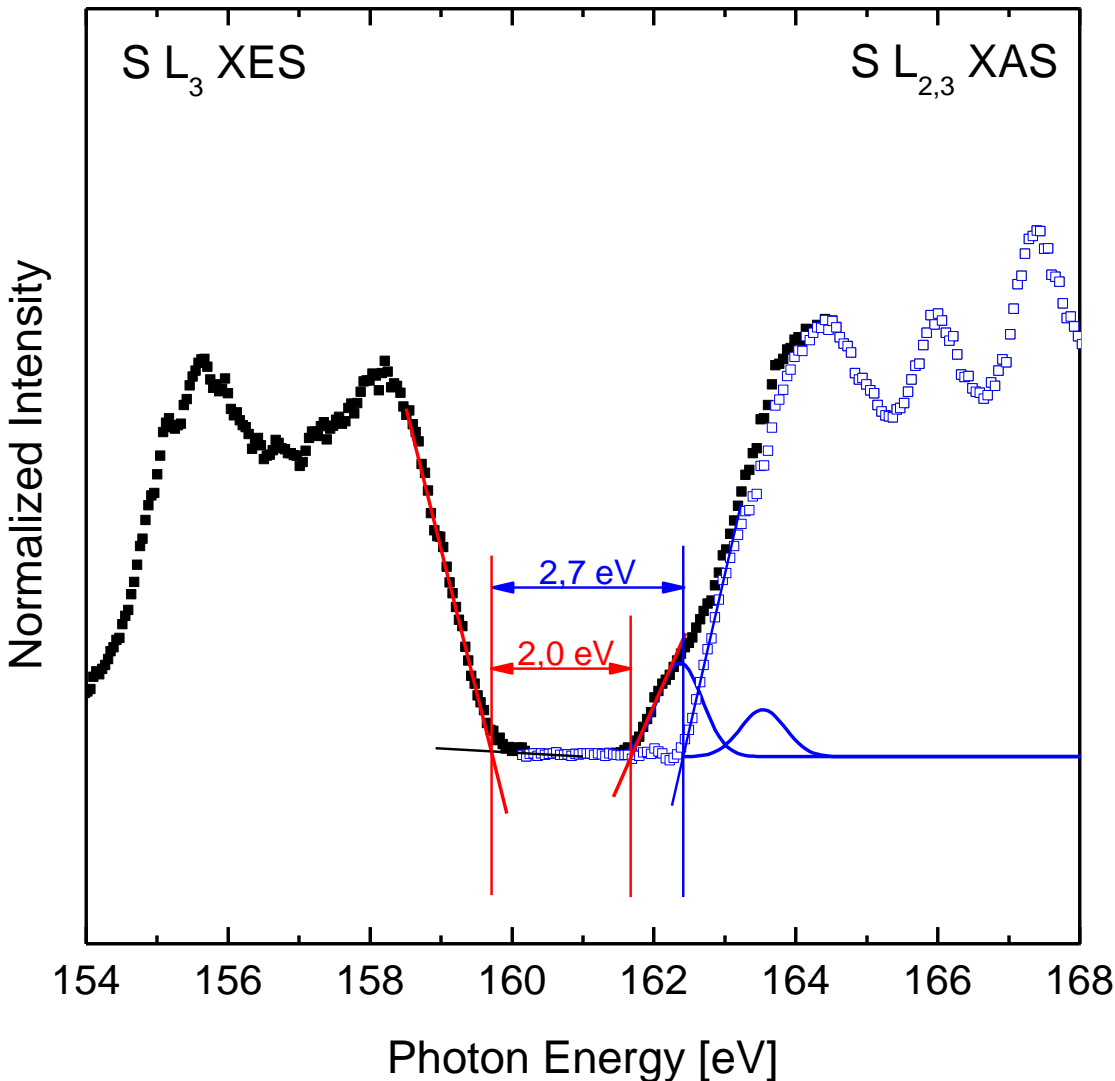
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- XES & XAS probe “ E_g ”
(experimental uncertainty: ± 0.2 eV)
- Potential existence of core excitonic features in the XAS spectra



“ E_g ” is lower-bound approximation for the ground state band gap

CdS: Impact of core excitonic feature

Weinhardt et al., PRB 75, 165207 (2007).



E_g (CdS): 2.4 ... 2.5 eV

Landolt-Börnstein, Springer (2011)

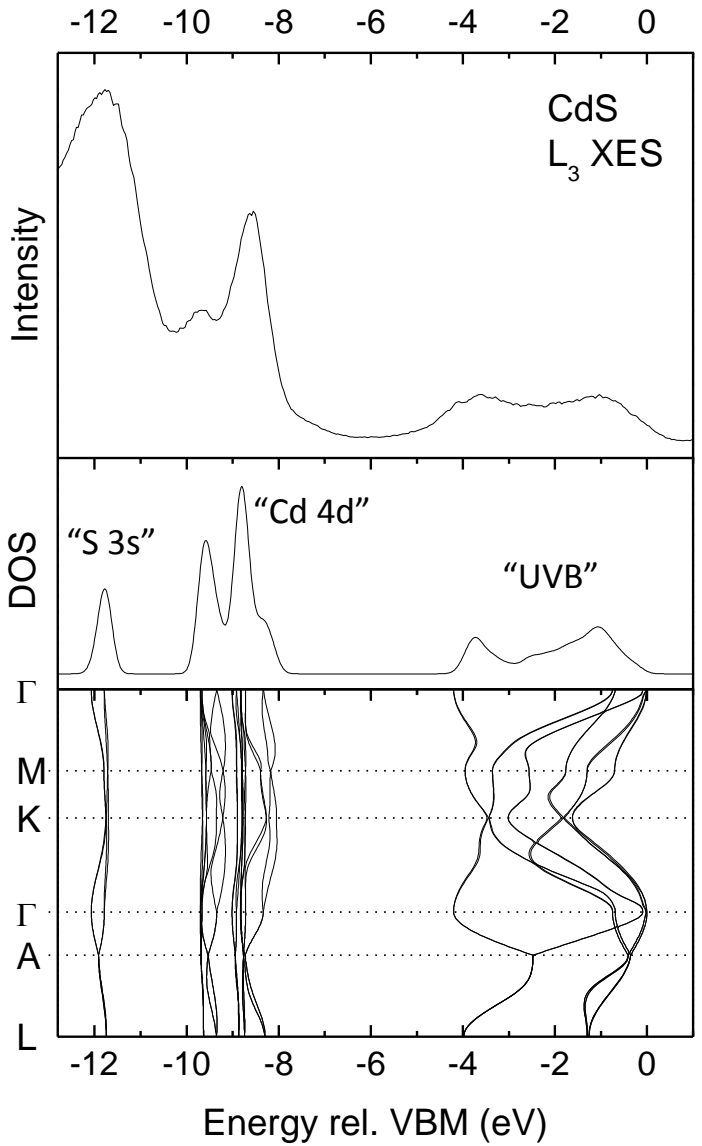
- “ E_g ” = 2.0 eV
- Taking core exciton into account (Gauss profile):
=> $E_g = 2.7$ eV



“ E_g ” is lower-bound approximation for the ground state band gap

Comparison with (validation of) calculated DOS

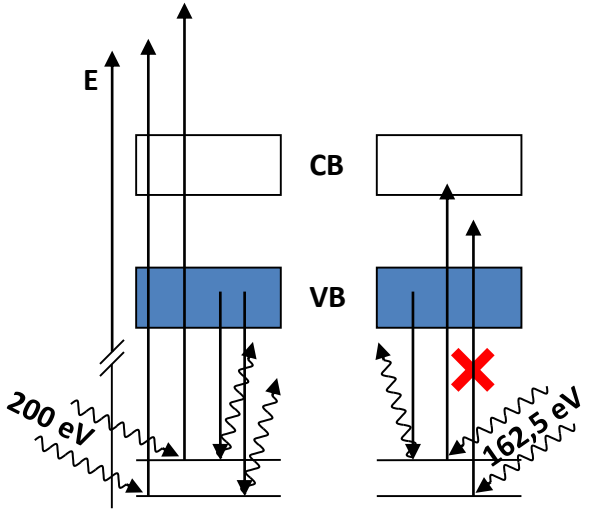
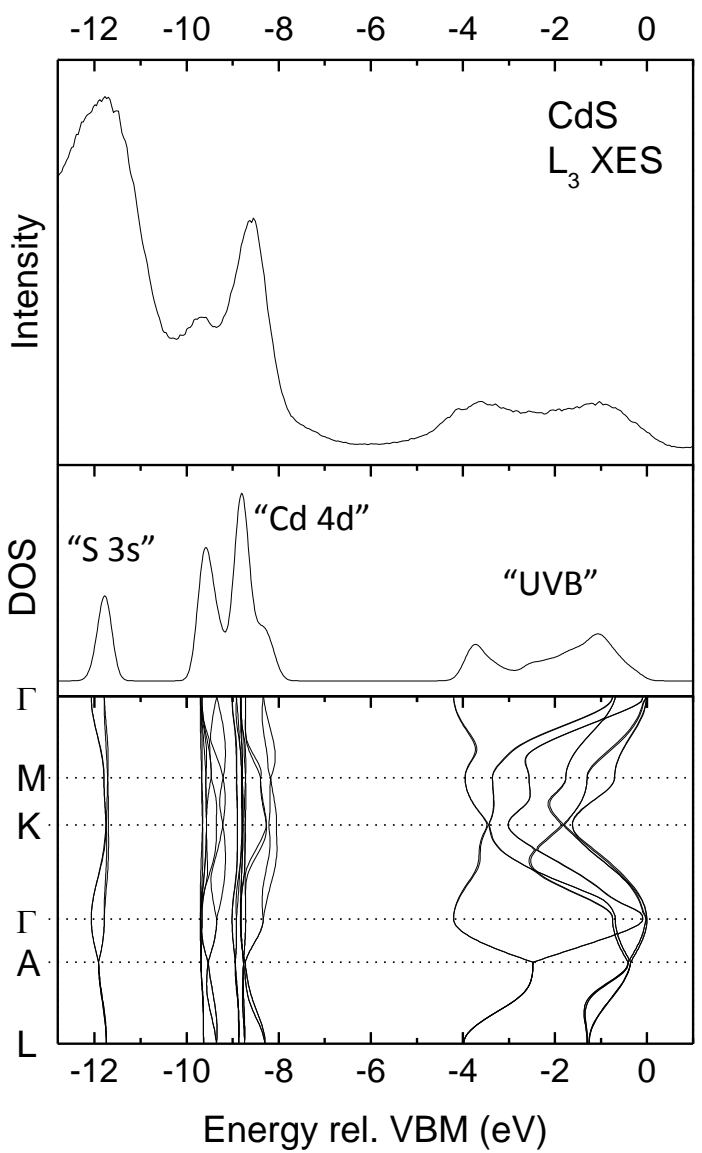
Weinhardt et al., PRB 75, 165207 (2007).



- XES represents (partial) density of states, DOS
- Comparison with calculated DOS useful to
 - => identify spectral contributions
 - => validate band structure calculations

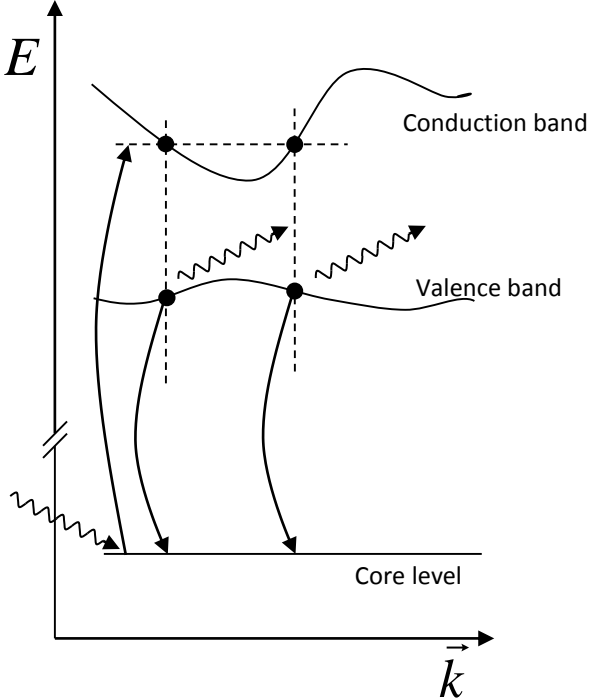
„Resonant“ excitation -> RIXS

Weinhardt et al., PRB 75, 165207 (2007).



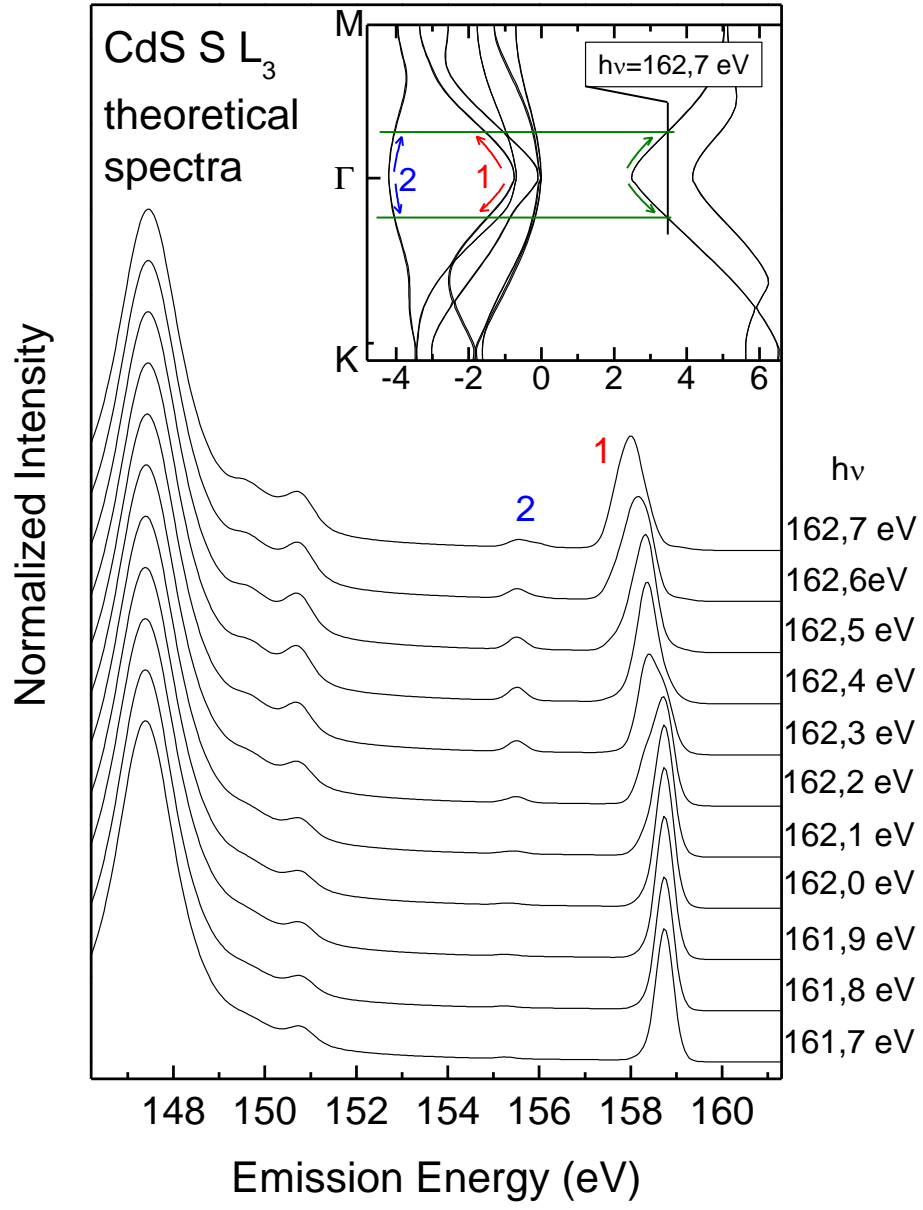
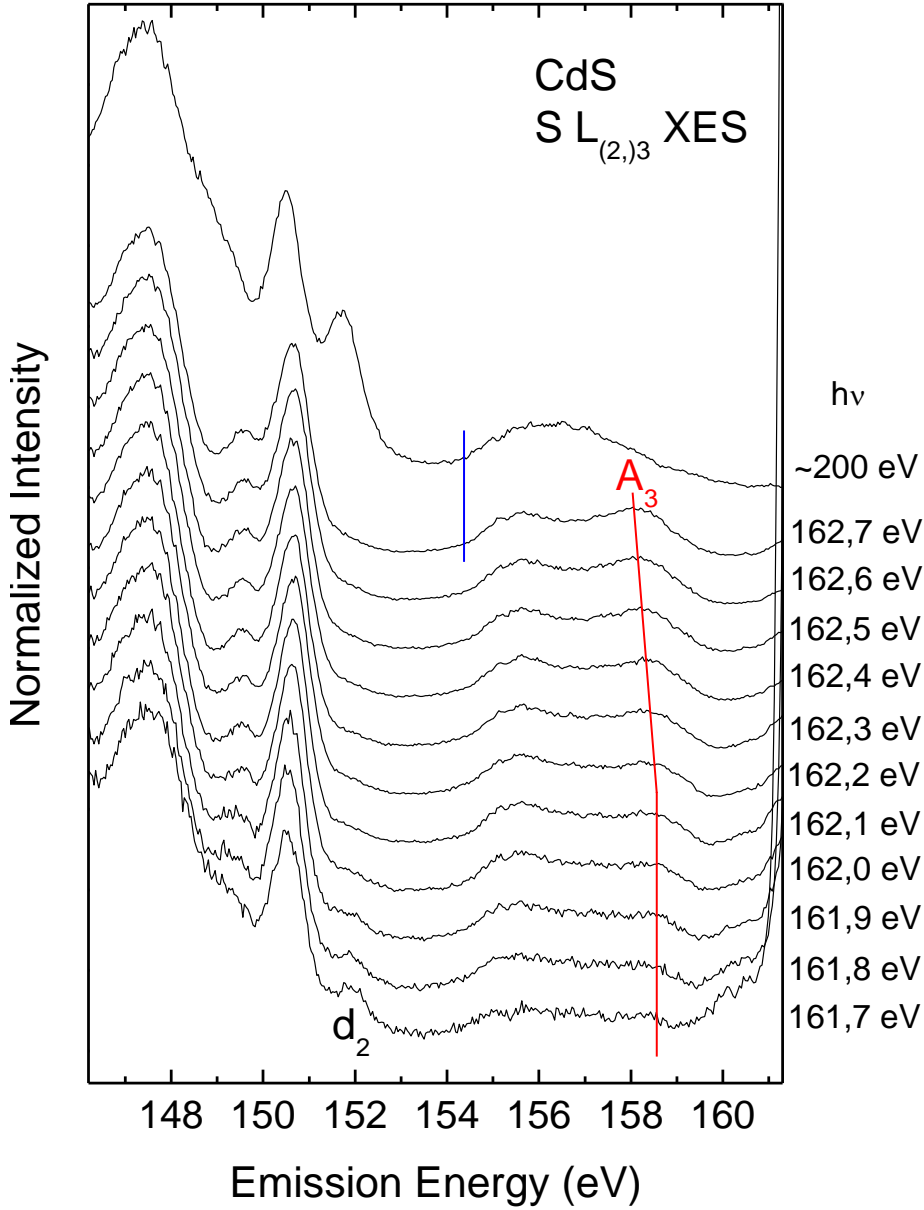
XES => RIXS

(Resonant Inelastic X-ray Scattering)



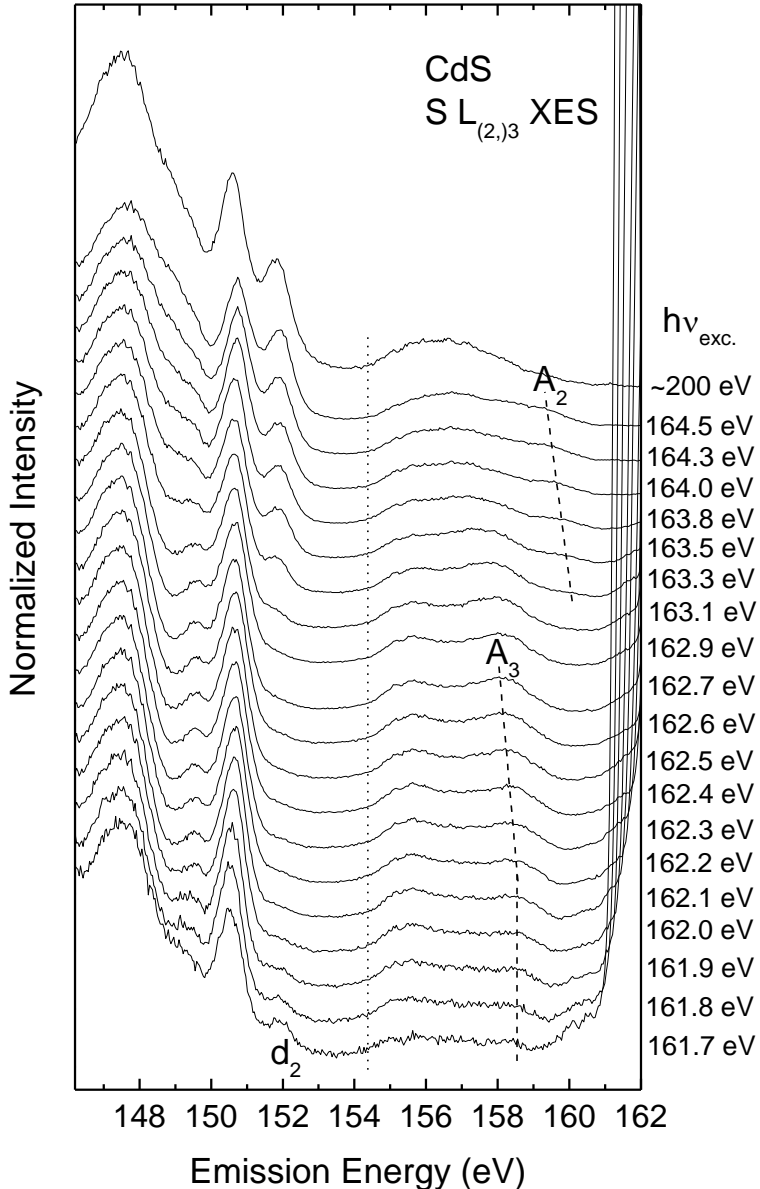
- Coherent emission, conservation of crystal momentum
- Selection of k vectors only through excitation energy

S L_{2,3} RIXS of CdS

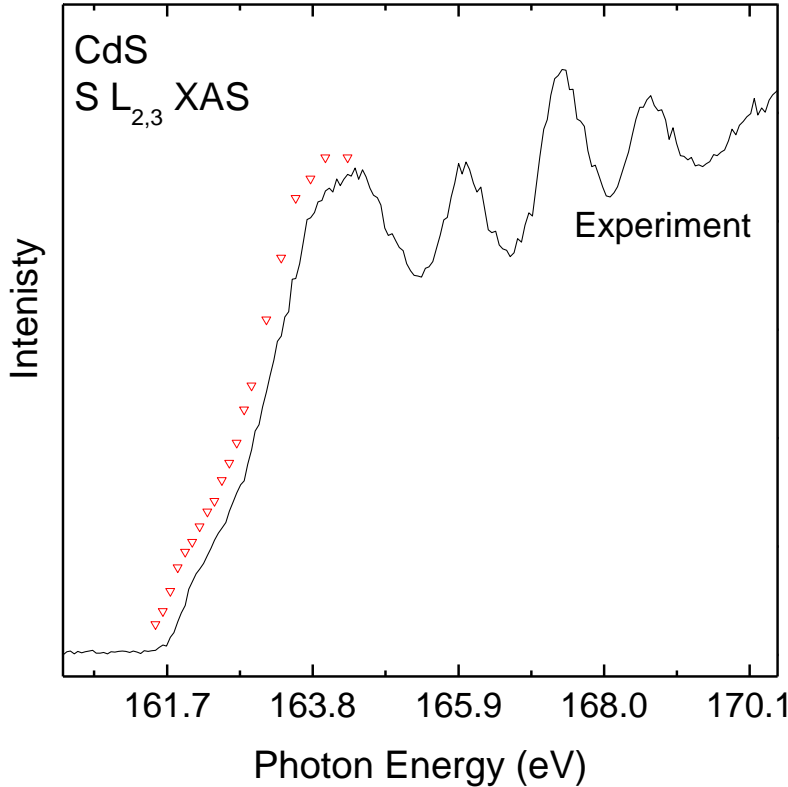


Weinhardt et al., PRB 75, 165207 (2007).

S L_{2,3} RIXS of CdS: Standard approach



- RIXS spectra measured at a series of energies around the absorption edge
- S L_{2,3} RIXS is tough: ~99.99% Auger
⇒ approx. 20 hours of measuring time for the complete series

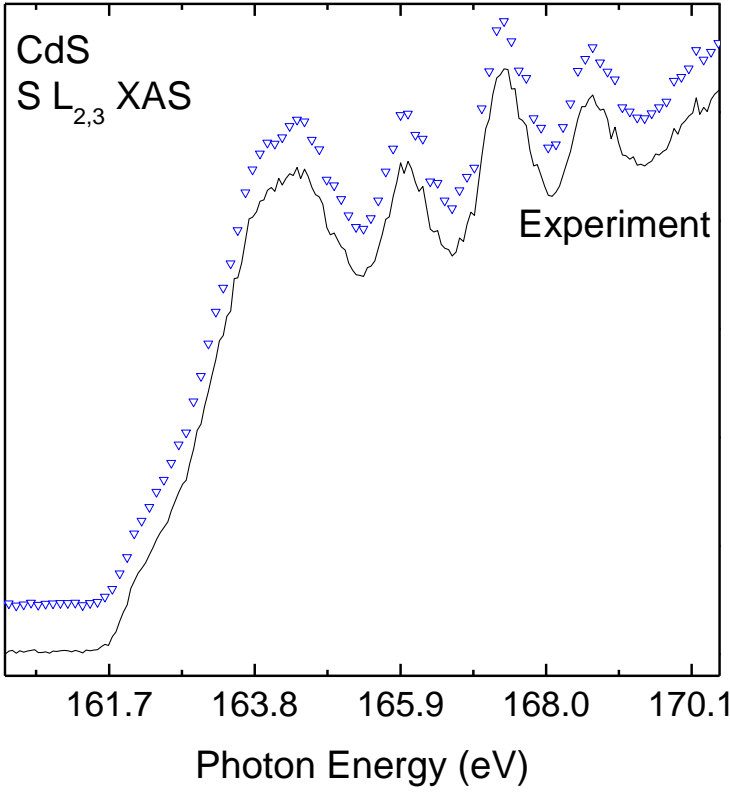


Weinhardt et al., PRB 75, 165207 (2007).

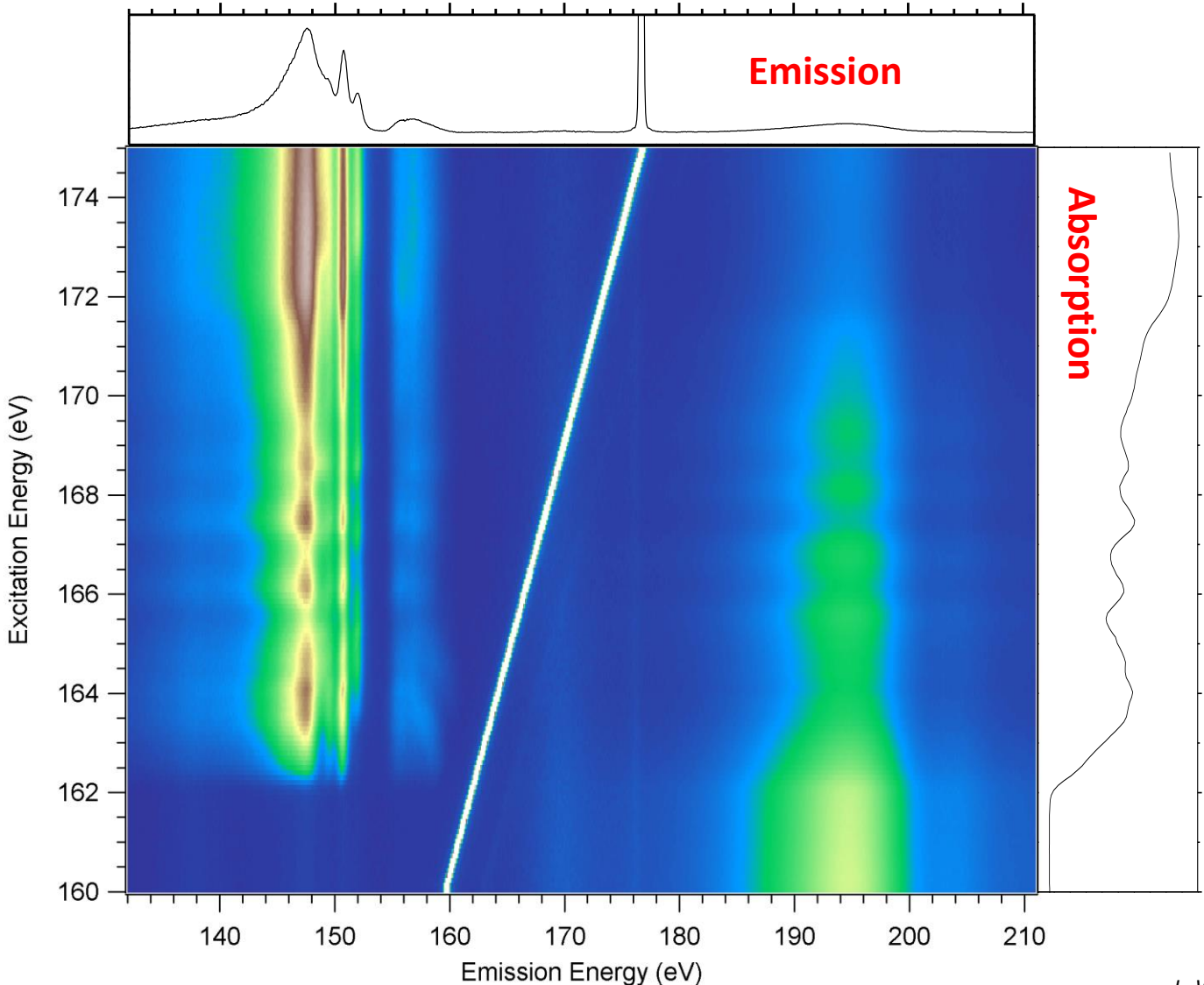
S L_{2,3} RIXS of CdS: New VLS spectrometer



- RIXS spectra measured at every point in the absorption spectrum
- Total measurement time: 33 min



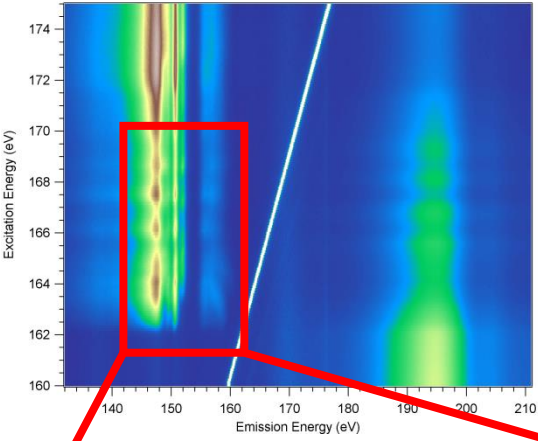
S L_{2,3} RIXS of CdS: RIXS map approach



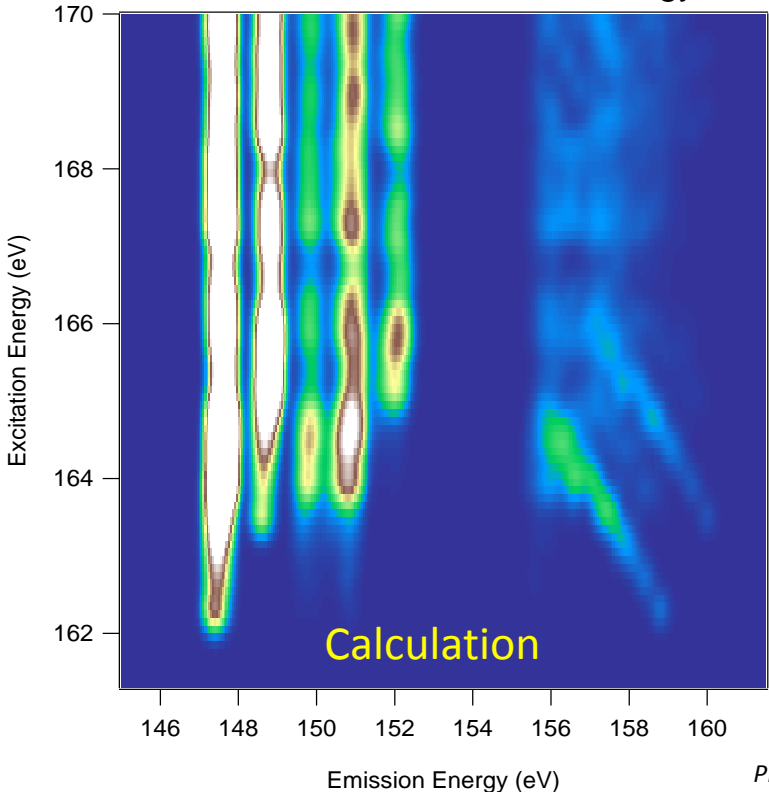
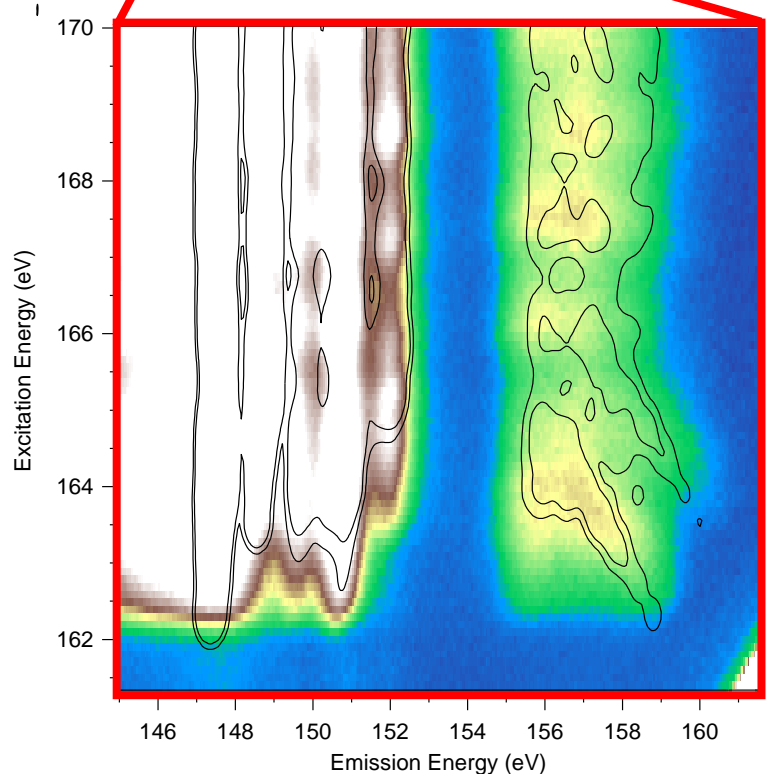
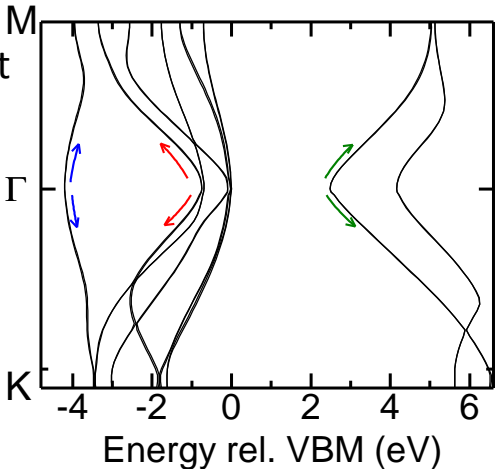
- Simultaneous measurement of RIXS and XAS
- => full electronic structure information**

L. Weinhardt et al., PRB 79, 165305 (2009).

S L_{2,3} RIXS of CdS: Validate theory with experiment



- Comparison of theory and experiment in entire k-space possible
- => Test and validate band structure calculations**



Research Example: Depth-resolved X-ray spectroscopy of mixed-halide perovskites

D.E. Starr,¹ G. Sadoughi,² E. Handick,¹ M. Gorgoi,^{1,3} S. Stranks, R.G. Wilks,^{1,3} H. Snaith,² M. Bär^{1,3,4}

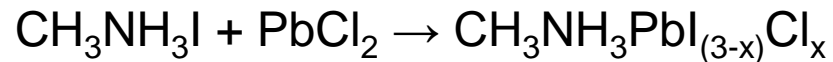


Motivation and sample preparation

We have used electron and X-ray based spectroscopies with different information depths to:

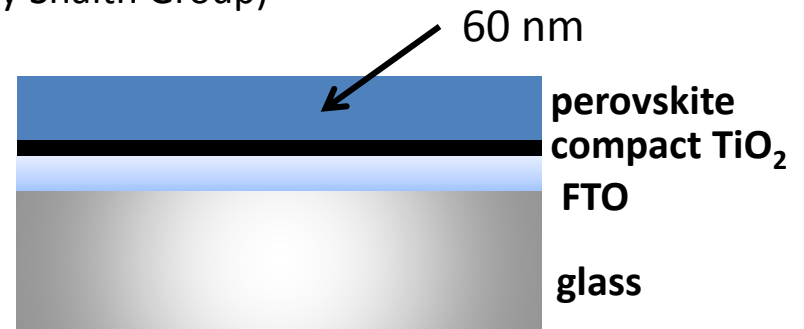
- measure core and valence levels of $\text{CH}_3\text{NH}_3\text{PbI}_{(3-x)}\text{Cl}_x/\text{TiO}_2$
- correlate the chemical and electronic properties of the *surface* and the *near-surface* region
- monitor the formation of the perovskite *in-situ*

Sample preparation¹:



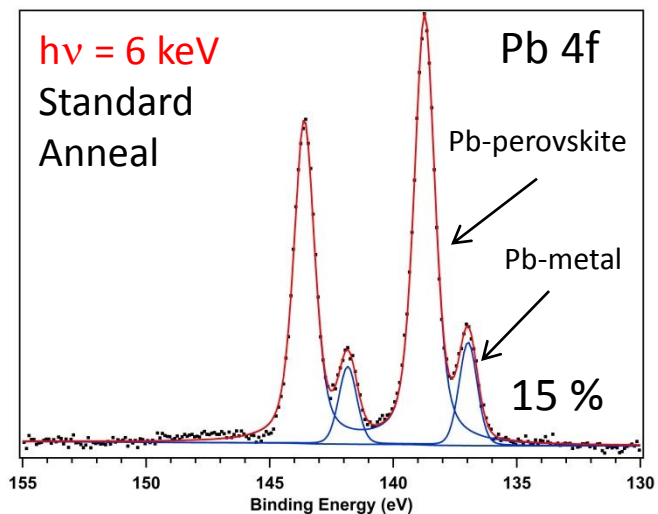
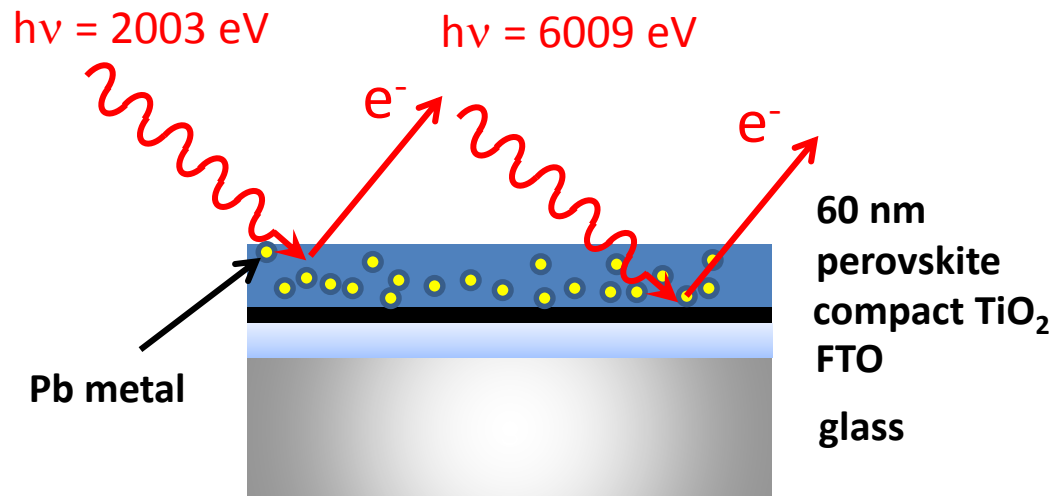
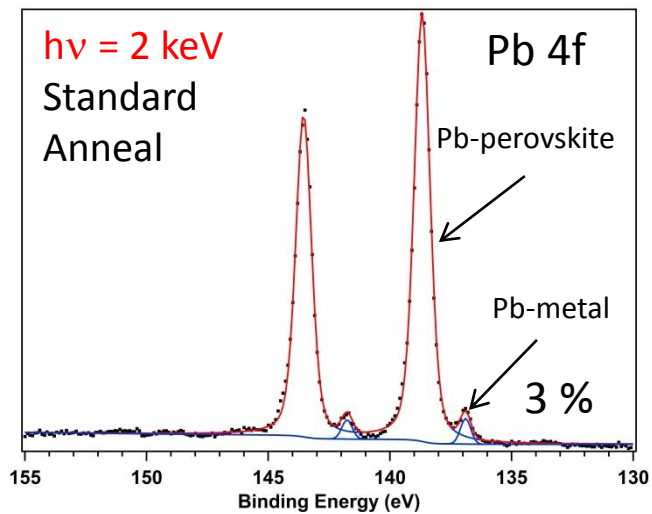
(Samples provided by Prof. Henry Snaith Group)

- 1) Solution of $\text{CH}_3\text{NH}_3\text{I} + \text{PbCl}_2$ in DMF spin-coated on compact TiO_2
- 2) Samples annealed in $\text{N}_2(\text{g})$ filled glove box at 90°C for 2h



¹Michael M. Lee *et al.* Science **338**,643 (2012)

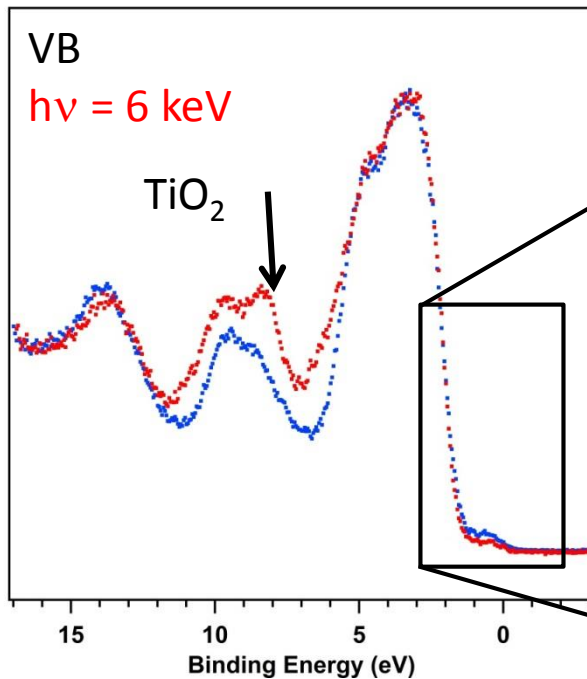
Pb 4f spectra: location of metallic Pb



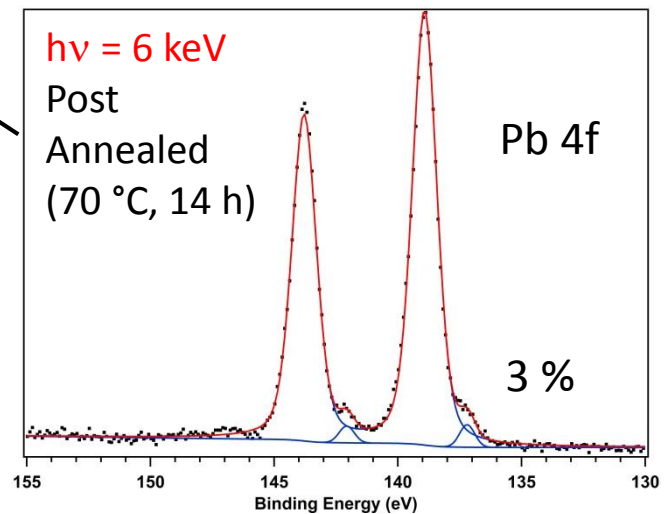
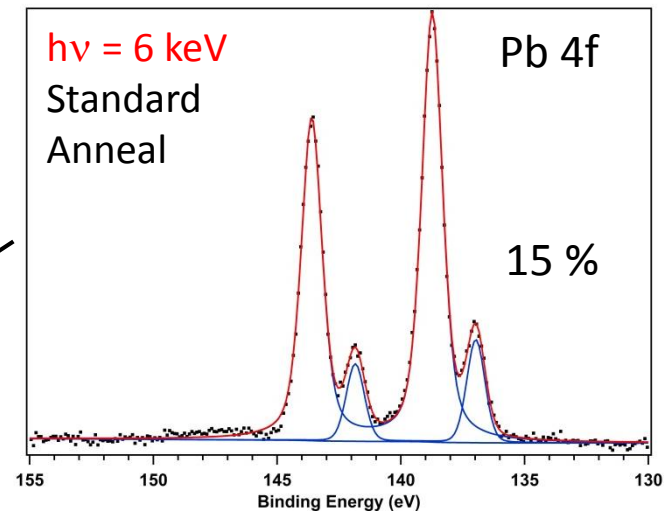
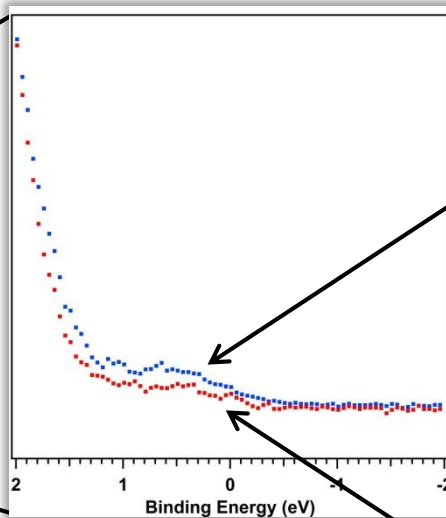
Most (but not all) samples indicate the presence of metallic Pb

If present, the concentration of metallic Pb is higher deeper beneath the surface

Valence Band Spectra: Metallic Pb



VB spectra 6009 eV



- Amount of metallic Pb correlates with density of occupied states near the Fermi level
- Amount of metallic Pb does not always decrease with annealing
- TiO₂ increase with annealing is likely due to some dewetting of perovskite film

In-situ perovskite formation in UHV

① Drop $\text{CH}_3\text{NH}_3\text{I} + \text{PbCl}_2$ in DMF solution* onto substrate



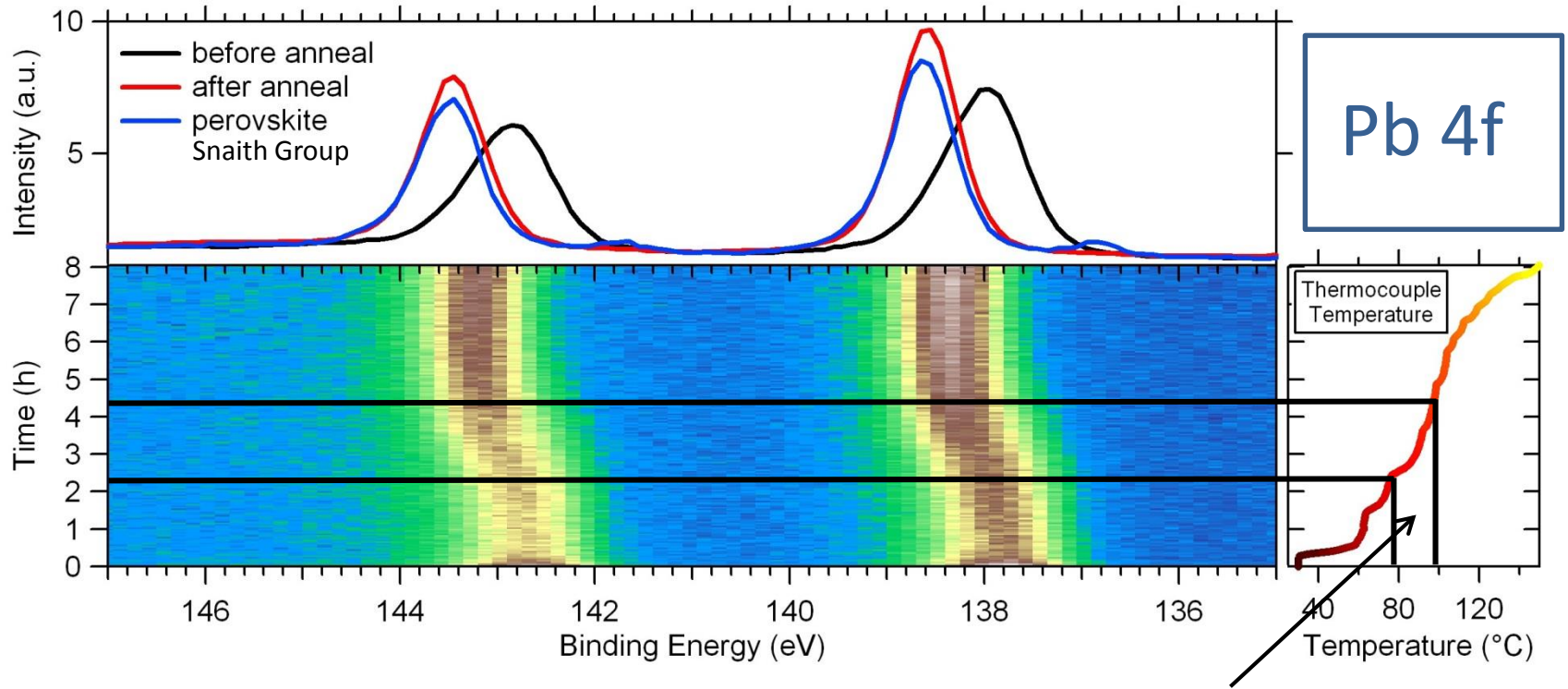
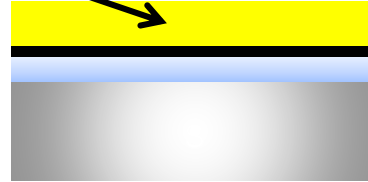
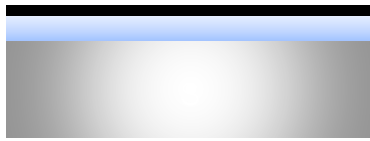
② Solution „dried“ in UHV chamber

Dried solution

Perovskite

③ Anneal in UHV, monitor XPS

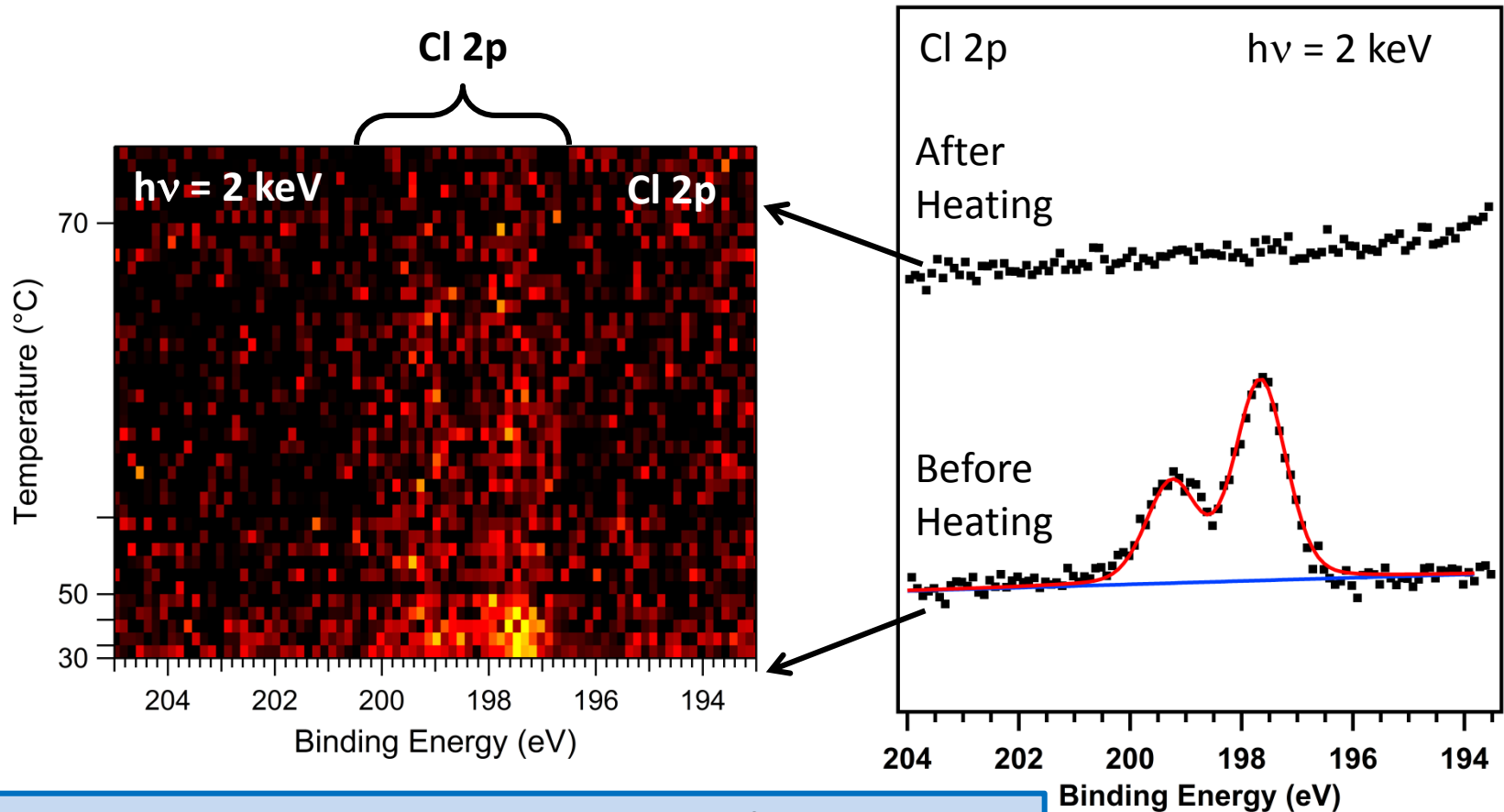
compact TiO_2
FTO
glass



*solution prepared @HZB

Transition Temperature 80 – 100 °C

Depletion of Cl in surface region

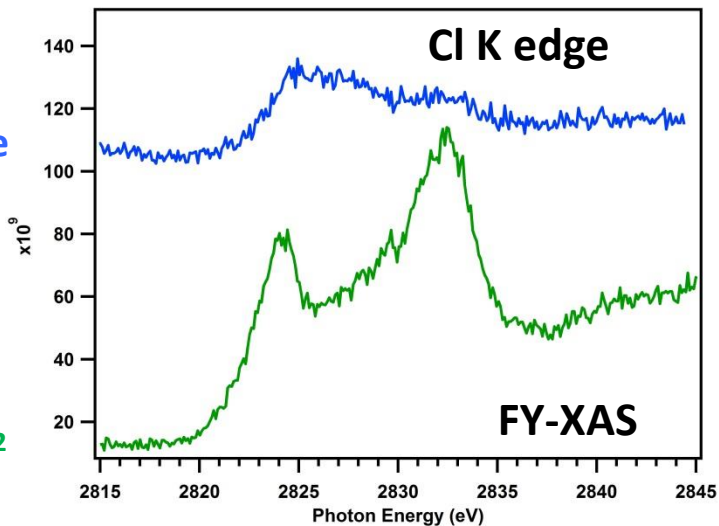
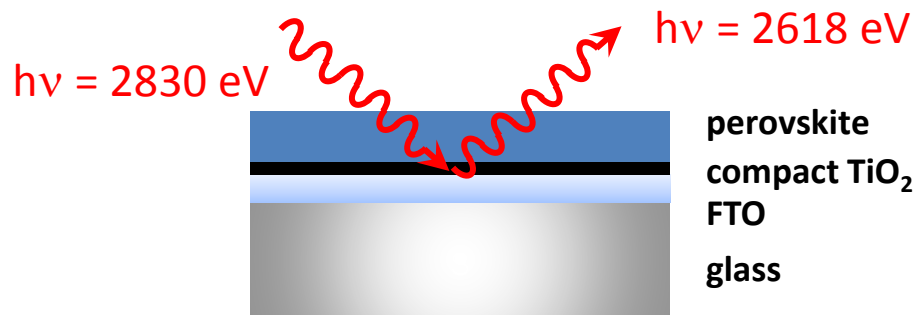
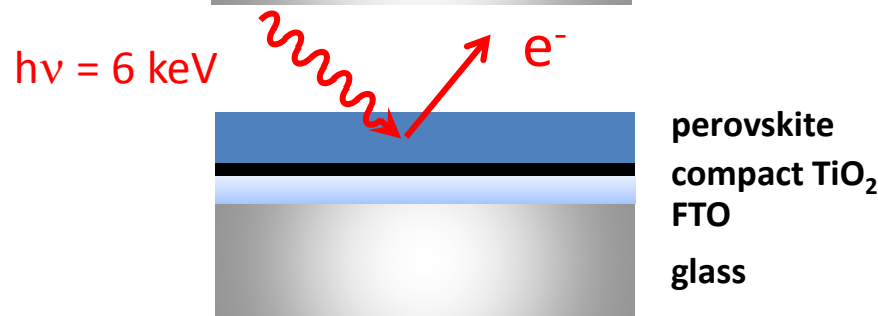
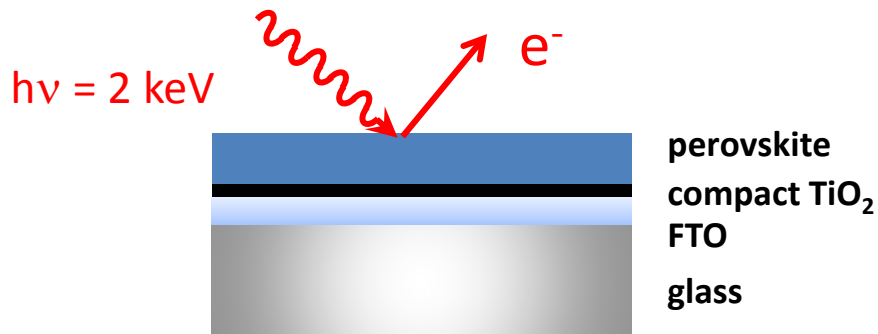
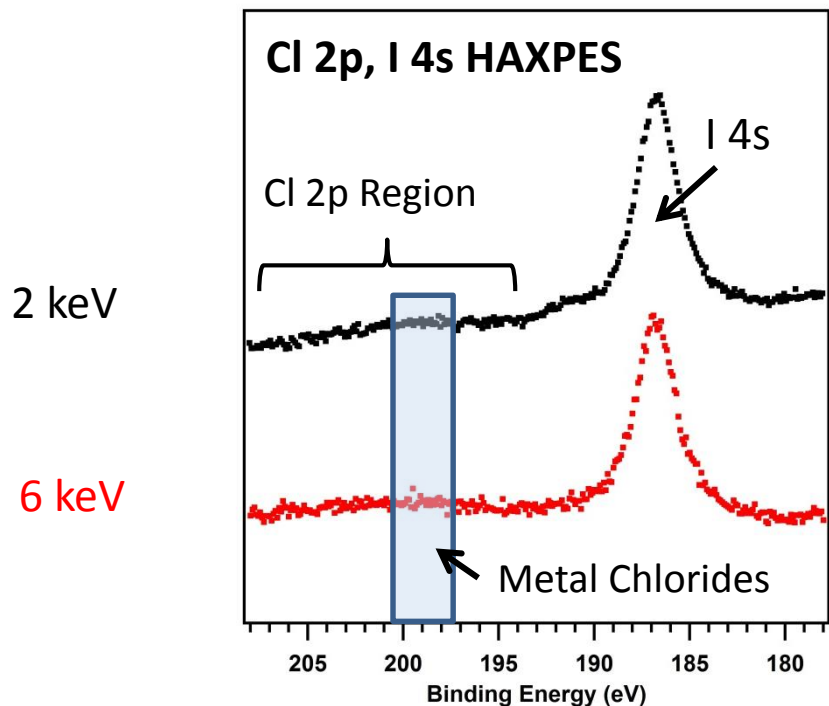


Cl 2p signal decreases drastically at the onset of annealing

Is depleted in surface region at low temperatures (< 50 °C)

Where does Cl go?

Cl 2p XPS and Cl K edge XAS: Where does the chlorine go?



Cl K edge XAS reveals Cl deep in perovskite

Cl concentration is higher in the bottom half of the 60 nm thick film than near the surface

Cl also observed in TiO₂ substrate but different species

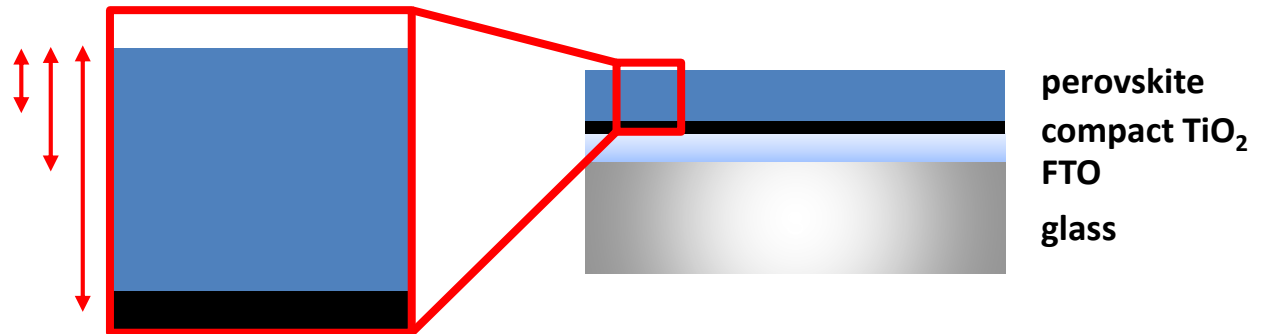
Where does the chlorine go?

x in $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$

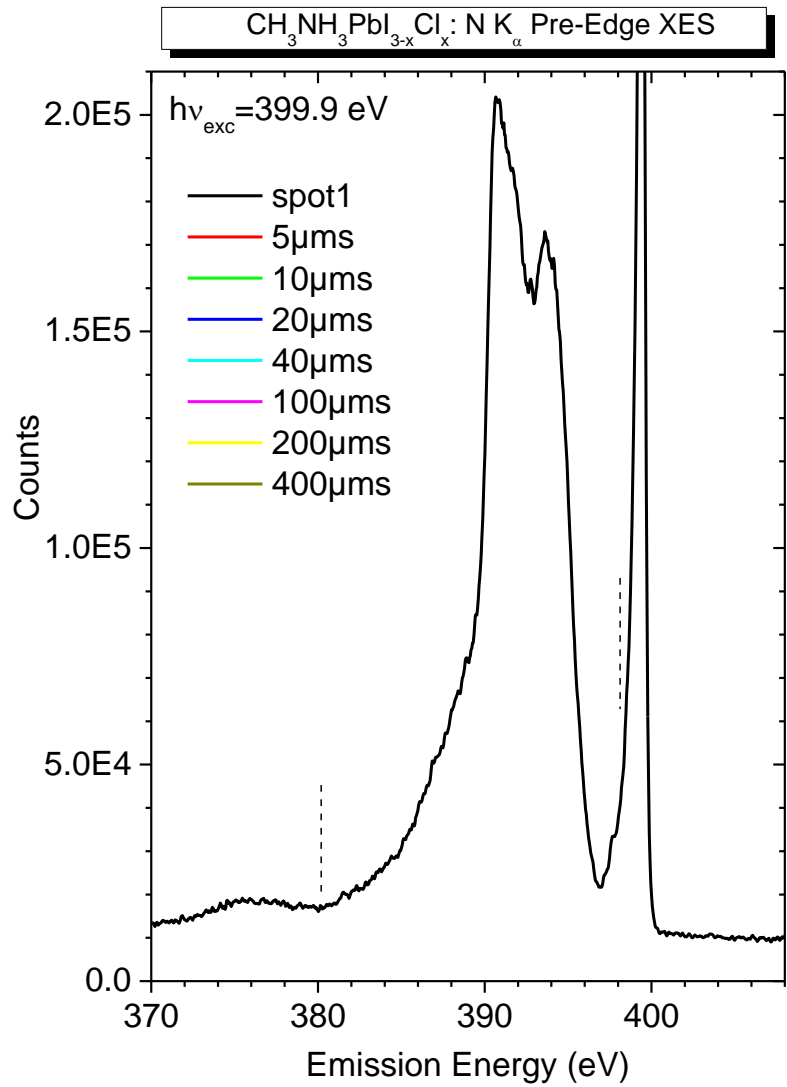
< 0.07 → 10 nm

< 0.40 → 26 nm

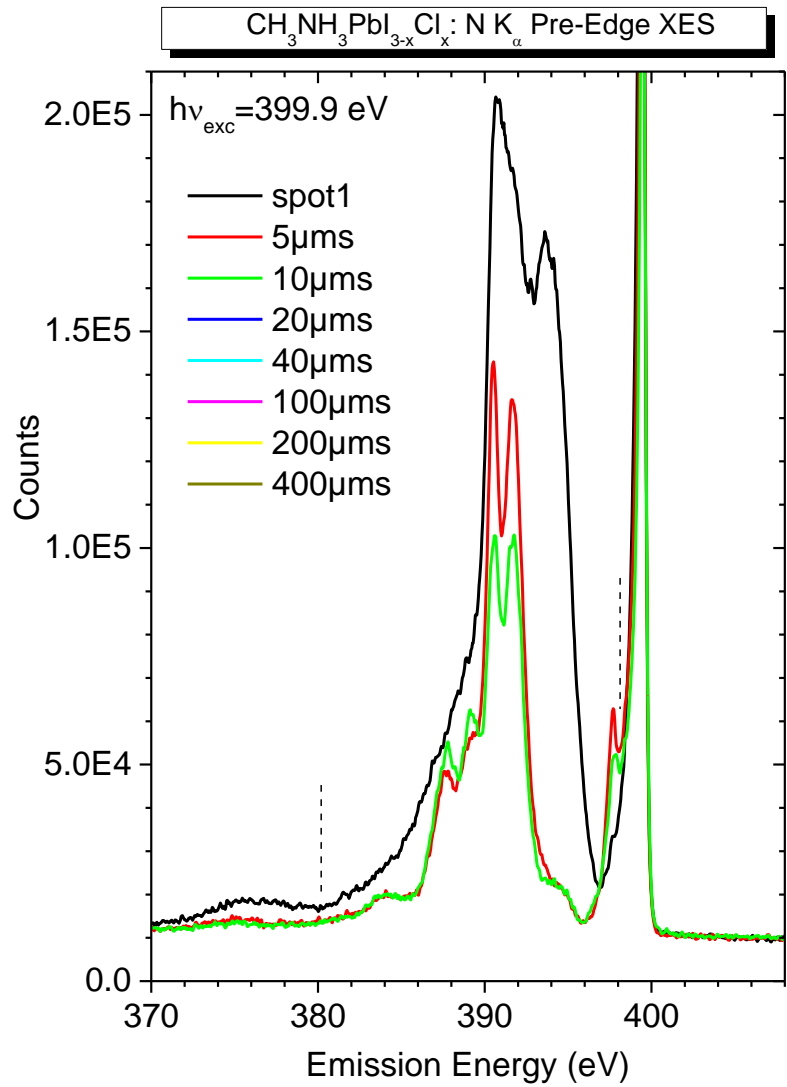
≥ 0.40 → > 26 nm



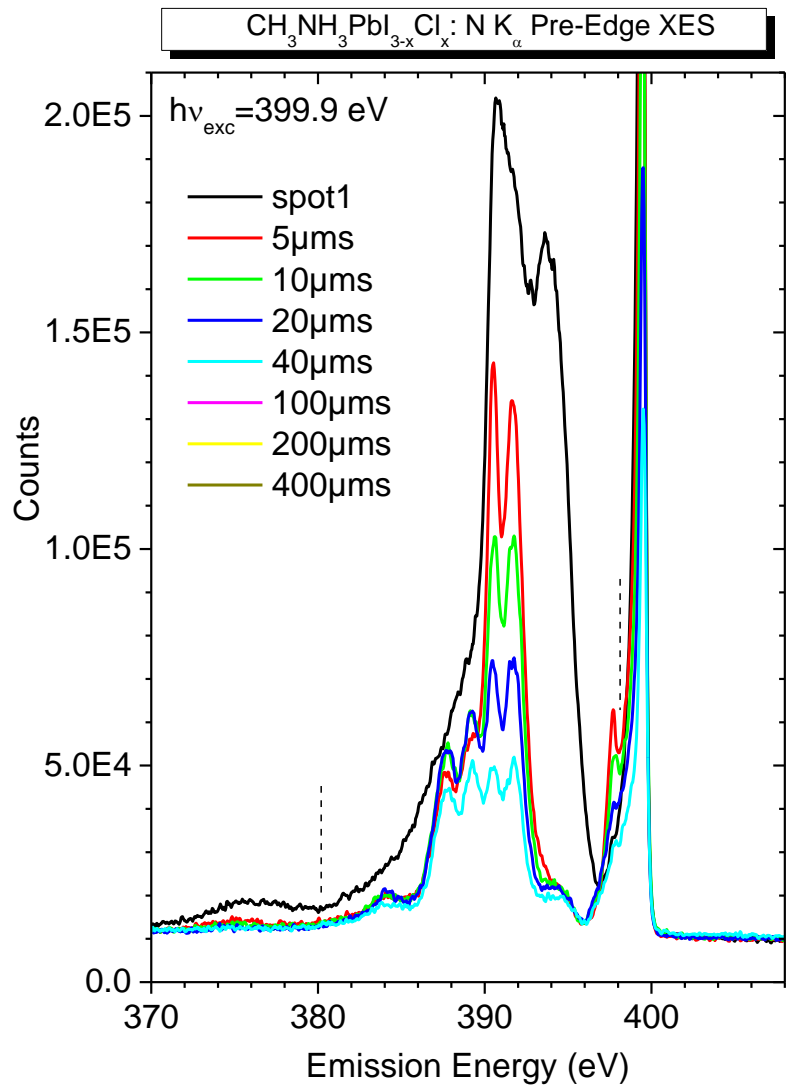
XES: Beamdamage?



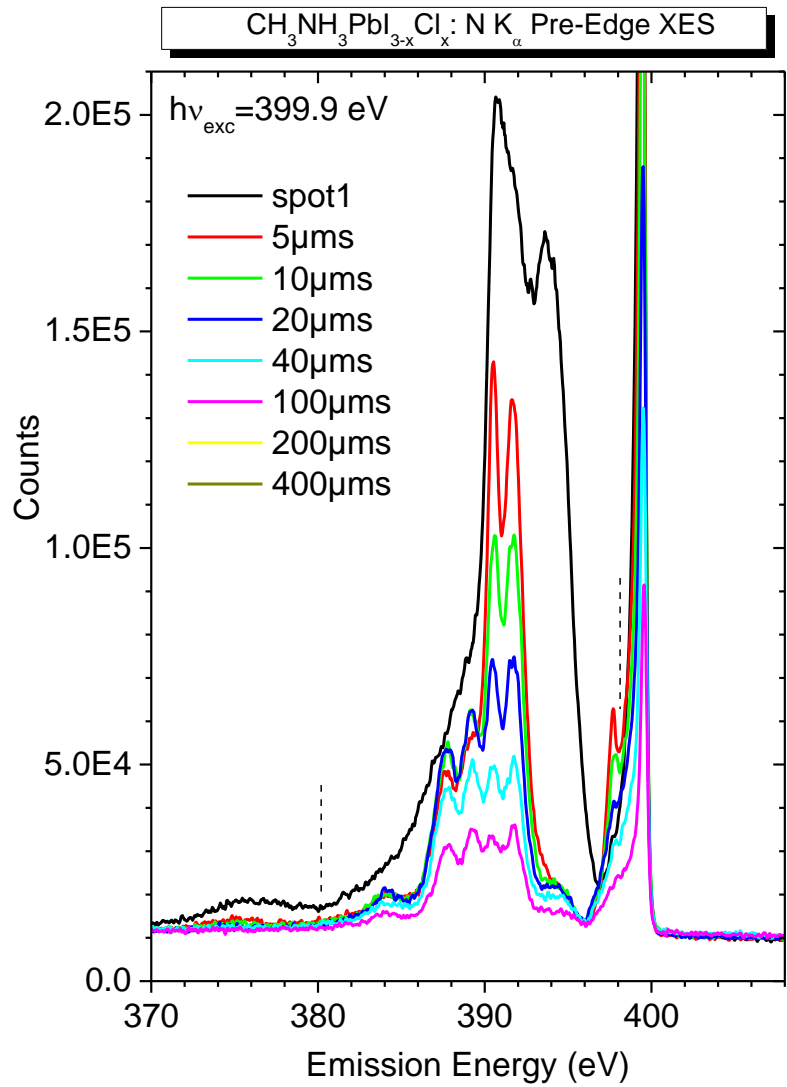
XES: Beamdamage?



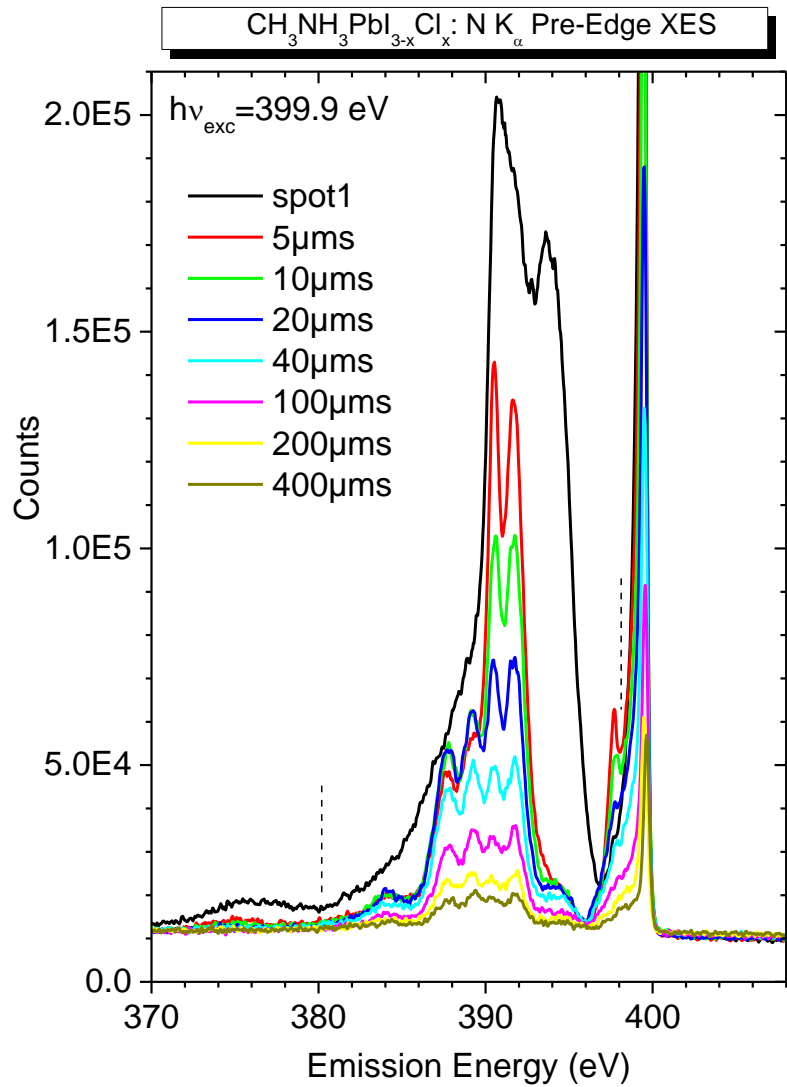
XES: Beamdamage?



XES: Beamdamage?



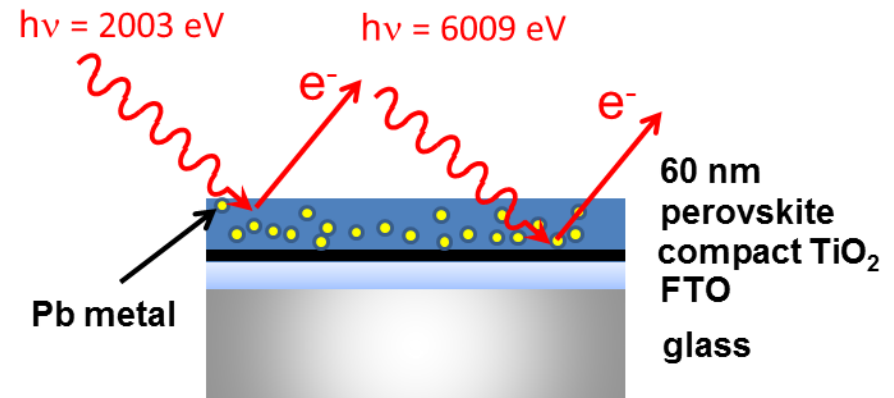
XES: Beamdamage????!!!!!!!



- N K XES spectra indicate that CH₃NH₃PbI_{3-x}Cl_x is altered in x-ray beam

Summary

- X-ray spectroscopies are well suited to probe the chemical and electronic properties of perovskite-based cell structures
- If observed, metallic Pb increases in its concentration with increasing bulk sensitivity
- No (within the detection limit) Cl is present at the surface of mixed halide perovskites
- Cl concentration increases towards TiO_2 substrate
- Beware of beamdamage





The Energy Materials In-situ Laboratory (EMIL) at BESSY II:

SISSY @ EMIL



Energy Materials In-Situ Lab Berlin



Solar Energy Materials In-Situ
Spectroscopy at the Synchrotron:

CATalysis Research for
Energy Storage (MPG/FHI)

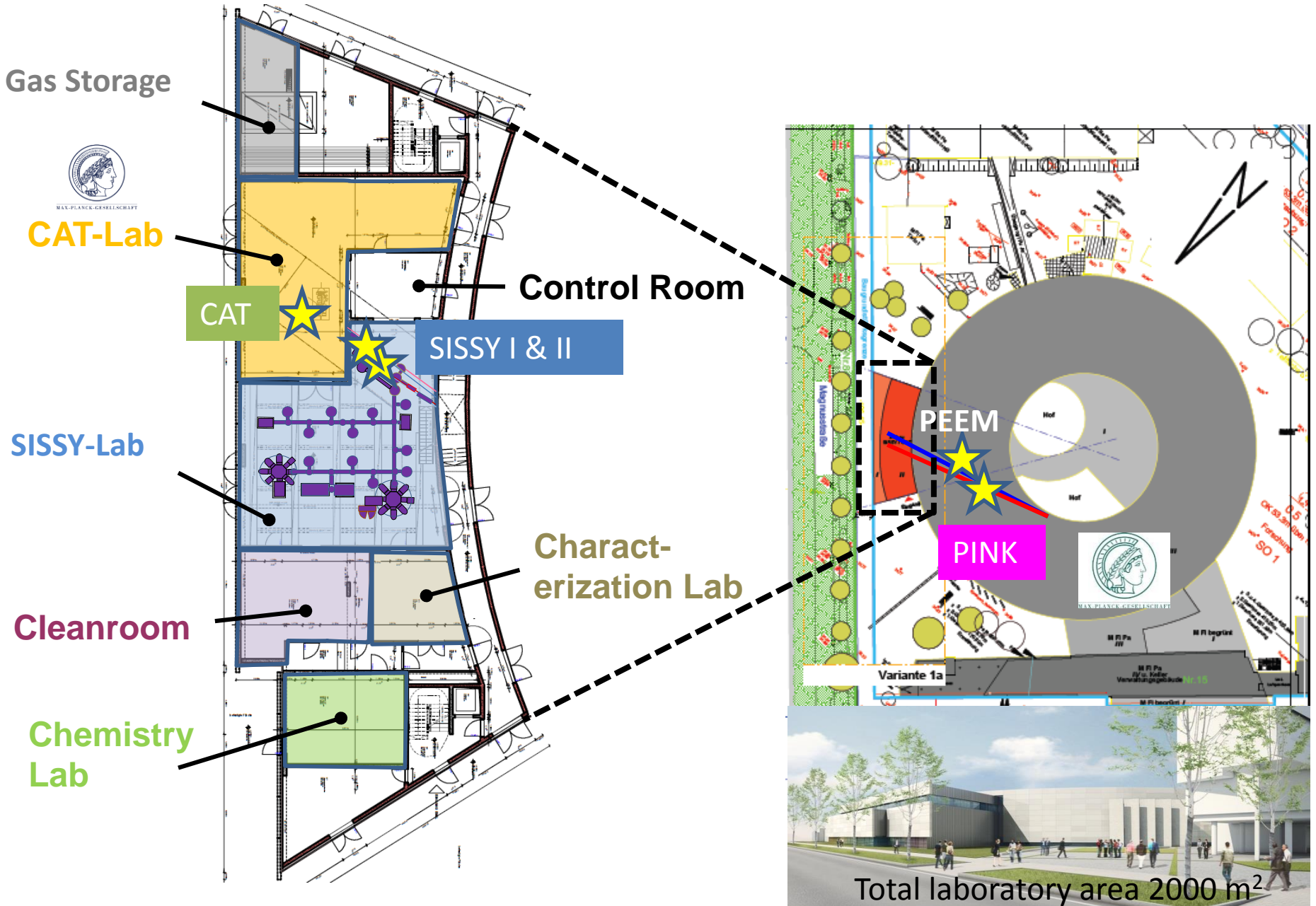
Research alliance between HZB and MPG
Budget: 26.6 M€ (6.8 M€ HZB, 6.7 M€ MPG, 5.7 M€ BMBF, 7.4 M€ HGF)

Synchrotron-based analytics over large energy range (80 eV – 10 keV)

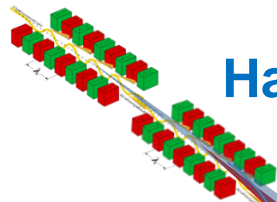
Synthesis and analytics of
thin-film materials

In-operando analysis of
catalyzers and processes

The EMIL Building (2000 qm)



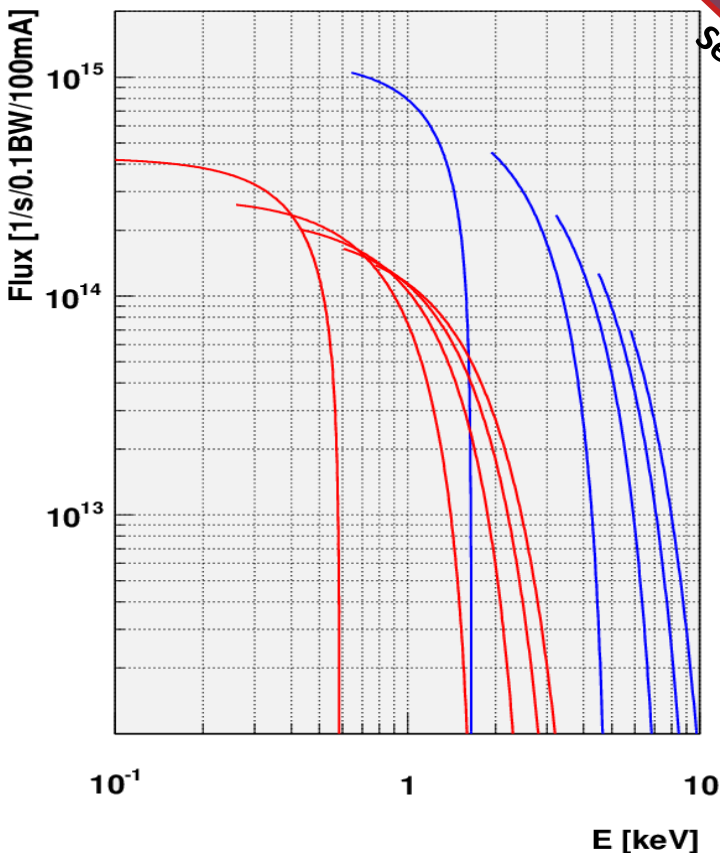
The EMIL beamline (80-10,000 eV)



Hard X-Ray: Cryogenic in-vacuum undulator U17

Soft X-Ray: Elliptical undulator UE48

20 μm pointing stability over 65 m!



Monochromator Section

PINK: non-resonant XRF

PINK

SISSY I: ARPES, XRF
XES, XAS

SISSY II: In-situ Spec.
HAXPEEM (FZJ)

UHV access to all
deposition systems

SISSY-1

PEEM

SISSY-2

CAT: near ambient
pressure XPS, in-situ
XRD/NAP-XPS

CAT

SISSY@EMIL: Analytics, Transfer, Cluster



Synchrotron-based x-ray analytics

(HAX)PES
XES
XAS
XRF

x-rays

Off-synchrotron analytics

UPS, CFSYS, IPES, XPS

UHV storage

Pulsed laser deposition

Glove Box

SISSY I

SISSY II



UHV transfer chambers

Preparation chambers

Sputter Tool

UHV transfer chamber

PECVD

UHV storage

Sample separation chamber



Silicon cluster tool

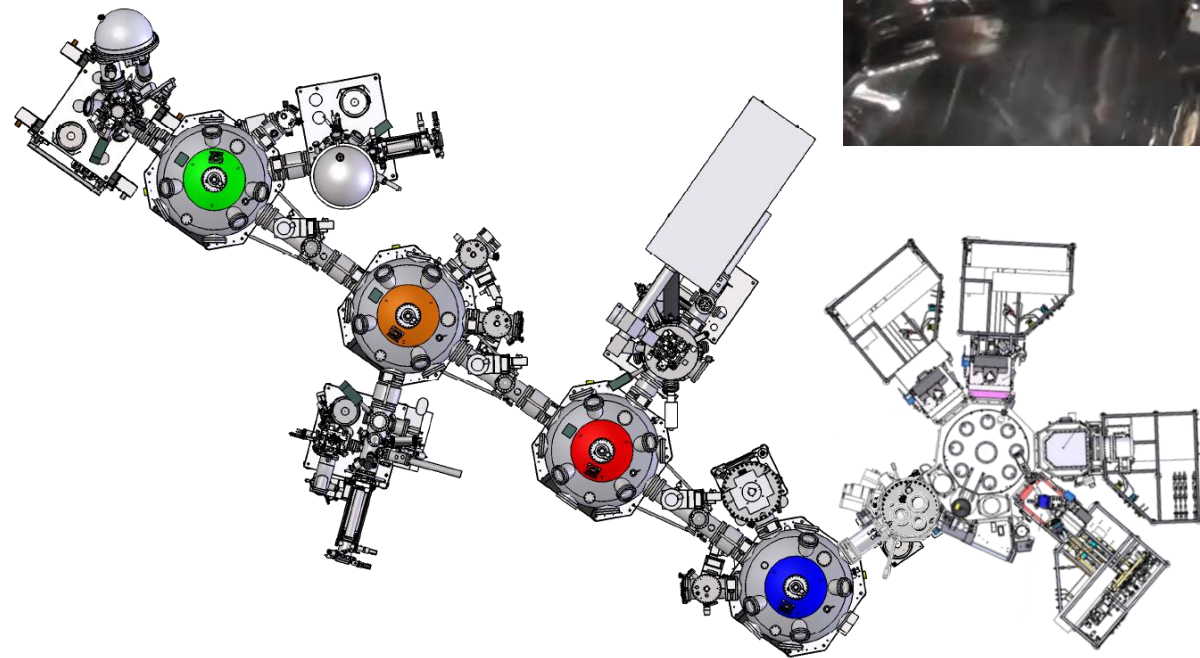
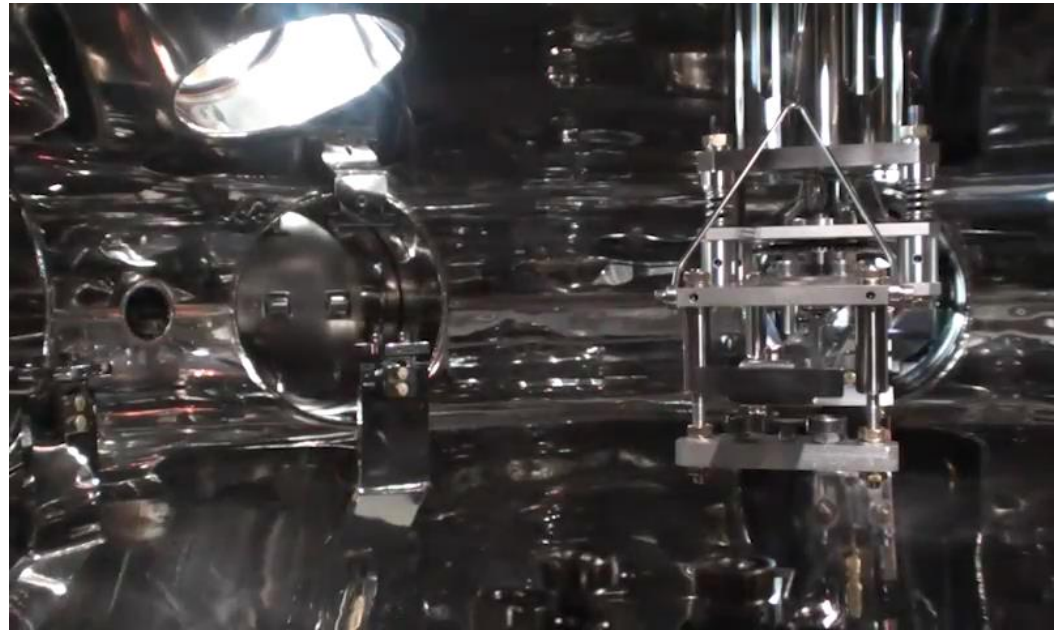
ALD

CFOT

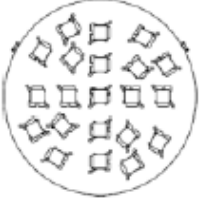



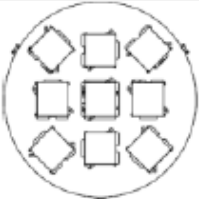



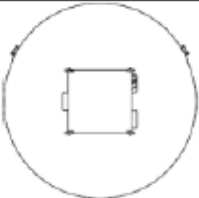



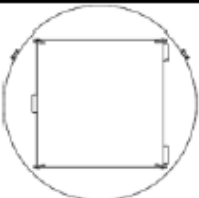

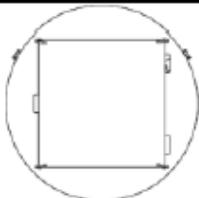

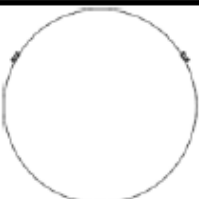



PVD

PVD

SISSY@EMIL: automated UHV transfer



Sample sizes, holders and adapters

Sample size [mm]	carrier	T = 90 K	T = 800°C	T = 1450°C
11x11				
25x25				
50x50				
100x100				
6"				

Can be used in Si-deposition system and UHV analytics

Can be used throughout the UHV analytics

T - sample temperature (max. / min.)

EMIL: Advantages for Energy Research

- Unique research environment
 - => deposition tools for thin-film materials directly connected to synchrotron analysis without vacuum break (*in situ & in system*)
- (Quasi) permanent access to the synchrotron
 - => feedback loop can be established
 - => knowledge-driven development of processes, materials, and devices
- Enable the establishment of a **world-class international user community and industry collaboration** at EMIL
- External User Philosophy
 - => Use existing and establish new collaborations with the leading researchers in the world
 - => Offer unique characterization and synthesis capabilities at EMIL
 - => User support understood rather in form of a collaboration than a service

→ Attractive to researchers from all energy materials communities and beyond...

Acknowledgements: EMIL

K. Lips: [Technical Project Head](#)

S. Raoux: [Head of Steering Committee, Nanospectroscopy/PEEM](#)

G. Reichardt: [Technical Director](#)

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T. Schulze, F. Fenske, O. Gabriel, K. Ellmer, M. Reiche: [Deposition tools](#)

•A. Knop-Gericke, M. Hävecker, R. Schlögl (MPG): [CAT analytics](#)

R. v. de Krol, K. Ellmer, K. Harbauer: [PLD](#)

Ch. Jung & team: [Domino](#)

A. Tallarek, J. Proszak: [Team assistance](#)

H. Schlender, I. Helms & team: [Communication](#)

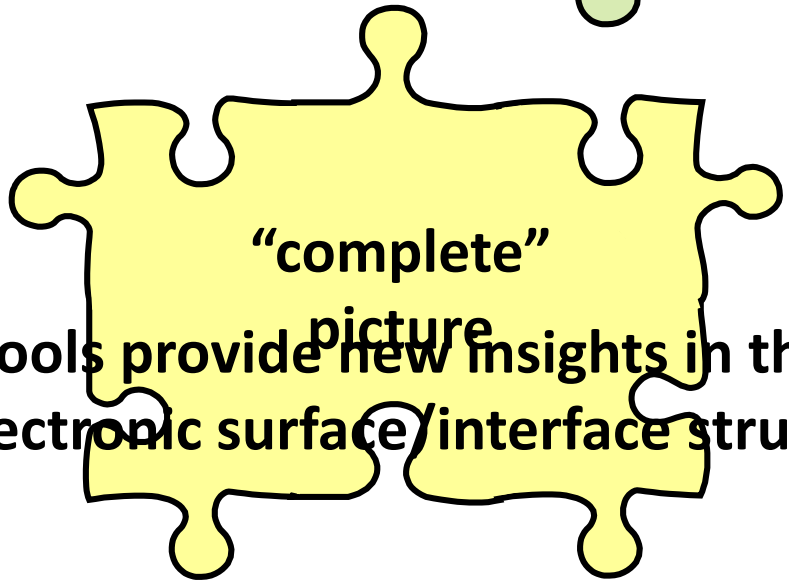
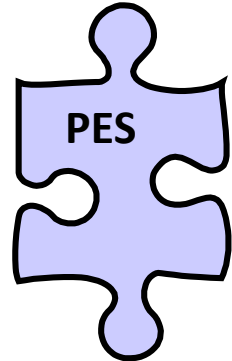
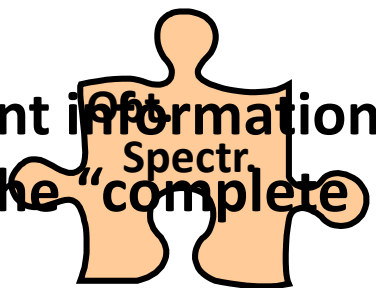
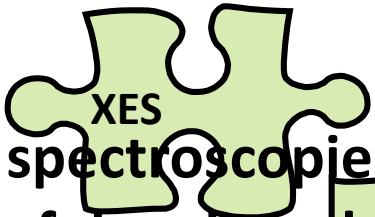
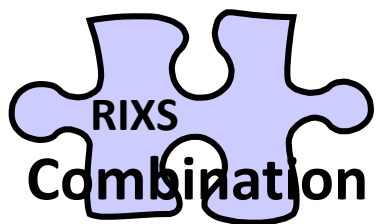
M. Gorgoi, W. Eberhardt: [Discussion and collaboration on HAXPES](#)

B. Rech, R. Schlatmann & team: [Renewable Energy Division at HZB](#)

Funding: BMBF, HGF, HZB, MPG



Combination of different spectroscopies (with different information depths) is very powerful and can help to reveal the "complete picture"!



Spectroscopic tools provide new insights in the chemical and electronic surface/interface structure!